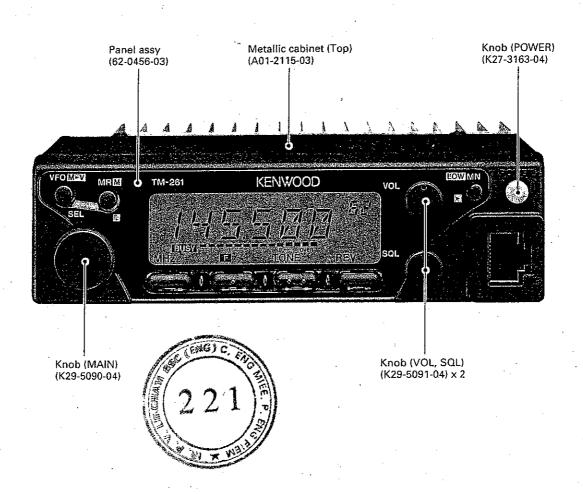
144MHz FM TRANSCEIVER

TM-261A

SERVICE MANUAL

KENWOOD

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CIRCUIT DESCRIPTION

CIRCUIT CONFIGURATION BY FREQUENCY

The TM-261A incorporates a PLL synthesizer which uses a digital VFO to allow any channel step of 5,10,12.5,15,20 or 25kHz to be selected (See Figure 1).

The receiving system utilizes double-conversion techniques. That is, an incoming signal is mixed down to the 1st intermediate frequency (IF) of 10.7MHz (M,M2,M3), 30.825MHz (K), using a 1st local oscillator frequency of from 105.175 to 166.820MHz (K),

133.300 to 135.295MHz (M), 125.300 to 163.295MHz (M2,M3). The 1st IF signal is then mixed with the 2nd local oscillator frequency of 10.245MHz (M,M2,M3), 30.370MHz (K) to generate the 2nd IF of 455kHz.

The transmitting system consists of a PLL circuit which allows direct modulation and direct frequency division. Signals from the PLL circuit are amplified by a linear amplifier for transmission.

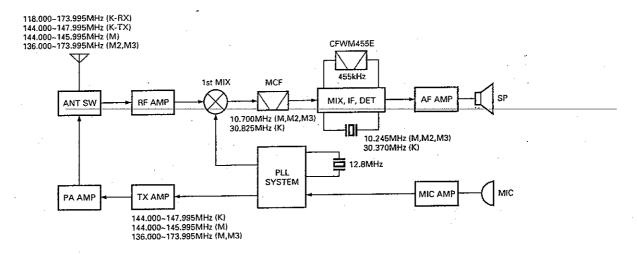


Fig. 1 Frequency configuration

RECEIVING SYSTEM

Overview

Incoming signals from the antenna pass through a low-pass filter in the final block of the transmitter system via a receive/transmit switch diode.

The signals are then passed through the band-pass filter (BPF) by the single-stage vari-cap tune circuit, where the high-frequency components are amplified by a GaAs FET. The signals are then fed into a three-stage band-pass filter that uses vari-cap tuning to reject unwanted signal components, and is fed to the 1st mixer. The 1st mixer uses the N-channel MOS FET (Q4) that are used in the RF stage to obtain better two-signal characteristics. The 1st mixer mixes the signal with the 1st local oscillator frequency and converts it to the 1st IF (10.7MHz (M,M2,M3)), 30.825MHz (K)). The signal than passes through two-stage monolithic crystal filters (MCF) to remove unnecessary near-by frequency components. The signal from the MCF is used as the 1st IF signal.

The 1st IF signal is amplified and fed into IC1 (KCD10) in the FM IF HIC. The IF signal is then mixed with the 2nd local oscillator frequency of 10.245MHz (M,M2,M3), 30.370MHz (K) to generate the 2nd If of 455kHz. The 455kHz signal is then passed through a six element ceramic filter (CFWM455E), and fed back into IC1 for additional amplification. The output signal from the IC1 is then fed into a power amplified via the audio volume control for application to the speaker.

S-meter circuit

S-meter control voltage from IC1 (KCD10) in the FM IF HIC is fed into the control unit. The CPU converters the voltage from an analog to digital signal in order to operate the LCD bar meter.

CIRCUIT DESCRIPTION

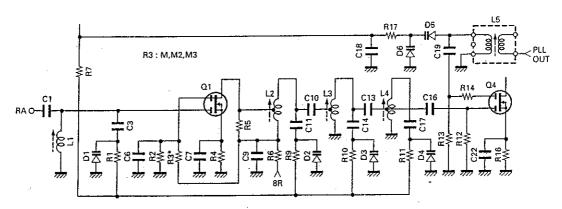


Fig. 2 Front-end section (Vari-cap tuning)

ltem	Rating
Nominal center frequency (fo)	10.700MHz
Pass bandwidth	±7.5kHz or less at 3dB
Attenuation bandwidth	±25kHz or less at 40dB
	±45kHz or less at 60dB
Ripple	1.0dB or less
Insertion loss	1.5dB or less
Guaranteed attenuation	70dB or more within ±1MHz
	Spurious :
	40dB or more at fo~fo+500kHz
	80dB or more at fo-(900~920kHz)
Terminating impedance	3kΩ/0pF

Table 1 MCF (L71-0228-15): TX-RX unit XF1 (M,M2,M3)

ltem	Rating		
Nominal center frequency (fo)	30.825MHz		
Pass bandwidth	±7.5kHz or less at 3dB		
Attenuation bandwidth	±28kHz or less at 40dB		
Ripple	1.5dB or less		
Insertion loss	3.0dB or less		
Guaranteed attenuation	60dB or more within ±1MHz		
	Spurious 40dB or more		
Terminating impedance	1.4kΩ/1pF		

Table 2 MCF (L71-0270-05): TX-RX unit XF1 (K)

ltem	Rating
Nominal center frequency (fo)	455kHz±1kHz
6dB bandwidth	±7.5kHz or more (from 455kHz)
50dB bandwidth	±15kHz or less (from 455kHz)
Ripple	3dB or less (within ±5kHz of 455kHz)
Insertion loss	6dB or less
(on the maximum point of output)	
Guaranteed attenuation	35d8 or more (within ±100kHz of 455kHz)
Terminating impedance	1.5kΩ

Table 3 Ceramic filter CFWM455E (L72-0366-05) : TX-RX unit CF1

TRANSMITTING SYSTEM

Overview

The transmitter produces the target frequency thru the use of direct FM-modulation via a vari-cap diode.

Modulation circuit

Voice signals from the microphone are fed into the microphone amplifier circuit of the control unit for amplification by the 1st transistor amplifier, and then into two operational amplifiers. These operational amplifier perform pre-emphasis, amplification, limiting, and includes a splatter filter, which is used to reduce undesirable high-frequency components from the signal. This signal is into the VCO of TX-RX unit.

The FM modulation circuit applies this signal directly to the VCO via a vari-cap diode.

· Younger-stage circuit

Signals from the VCO are applied to the drive HIC IC8 (KCB11). The amplifier always operates in a linear mode so that signals can be amplified without degradation. Additionally the amplifier is designed to cover a wide range of frequencies and can produce stable output without adjustment. The APC (Automatic Power Control) controls collector voltage from the last stage of the younger-stage circuit.

CIRCUIT DESCRIPTION

· Power amplifier circuit

The drive signal is amplified to the required level by the power module. The TM-261A uses a large heat sink to prevent failure of the final amplifier due to temperature. It is provide efficient radiation of the heat generated by the final amplifier.

APC circuit (Automatic Power Control)

The automatic power control circuit (APC) uses a diode to detect a portion of the output from the final module, It amplifies this signal and uses it as a control voltage, this control voltage is inversely proportion to the output so that a constant output is produced.

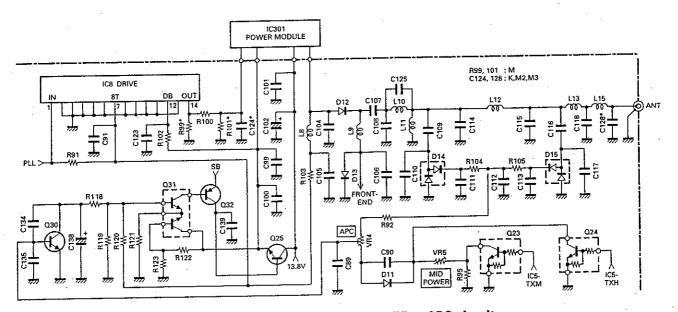


Fig. 3 Younger-stage, Power amplifier, APC circuits

(Tc=25°C)

Item	Symbol	Condition	Rating	Unit
	ļ		17	V
Operating voltage	Vcc			A
Current consumption	Icc		5	
Input power	Pin	f : 144~148MHz, Vcc : 12.5V, Zg=ZL=50Ω	200	mW
Output power	Po	f: 144~148MHz, Vcc: 12.5V, Zg=ZL=50Ω	.15	W
Operating case temperature	Tc(op)		-30~+110	°C
Storage temperature	Tstg		-40~+110	°C

Table 4 Power module M57715 maximum ratings (TX-RX unit IC301) : M

(Tc=25°C)

Item	Symbol	Condition	Rating	Unit
			16	V
Operating voltage	Vcc		16	V
Control voitage	Vcon	_ 1	14	A
Current consumption	łτ			
Input power	Pi		600	mW
Output power	Po	12.5V <vcc≤16v, pi="0~500mW," vcon≤12.5v,="" zg="ZL=50Ω</td"><td>65</td><td>W</td></vcc≤16v,>	65	W
	Tc(opr)		-30~+100	°C.
Operating case temperature	<u> </u>		-40~+110	°C
Storage temperature	Tstg		1	<u> </u>

Table 5 Power module S-AV17 maximum ratings (TX-RX unit IC301) : K,M2,M3

CIRCUIT DESCRIPTION

PLL SYNTHESIZER UNIT

A block diagram of the PLL and VCO unit is provided in Figure 4 and 5. In the TM-261A, the PLL system is implemented as a sub-unit which is divided into the upper VCO and lower PLL blocks. The sub-unit is shielded to prevent external interference.

There are two reference frequencies, 6.25kHz and 5kHz, available to allow 5,10,12.5,15,20,25kHz-step operation. The 6.25kHz is obtained by dividing the reference oscillator frequency of 12.8MHz by 1/2048, and the 5kHz is obtained by dividing it by 1/2560. The VCO directly generates the dial frequency. This dial frequency is amplified once and then fed into a pulse swallow-type PLL IC for frequency division and phase comparison, in order to lock the frequency.

The PLL system is locked without switching between transmit mode and receive mode. By using a signal ("L" in transmit mode) from pin 11 of the PLL IC (M54959FP), the LPF is deactivated-activated by Q52 and Q53 only for the moment when the TM-261A enters transmit mode. This helps produce lock more rapidly than previous methods.

Calculate example (M,M2,M3).

In 144MHz mode, fvco (RX) is calculated by the following formula;

fvco = $(144 - 10.700) = {(n \times 128) + A} \times fosc \div R$ where,

fvco: VCO output frequency

n : Binary value of the 10-bit programmable

A : Binary value of the 7-bit programmable counter

fosc: 12.8MHz reference frequency

R : Binary value of the 14-bit programmable counter 2560

In this case.

n = 208 and A = 36

Therefore, fvco is calculated as follows:

 $f_{VCO} = \{(208 \times 128) + 36\} \times 12800 \div 2560$

 $= (26624 + 36) \times 5$

= 133300 = 133.300MHz

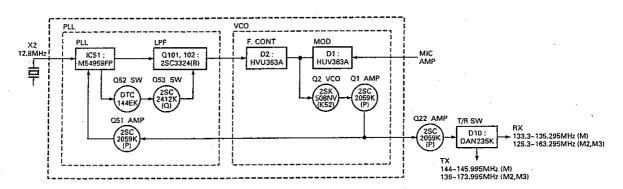


Fig. 4 PLL block daigram: M,M2,M3

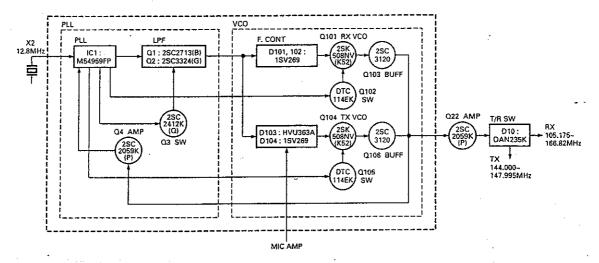


Fig. 5 PLL block diagram: K

CIRCUIT DESCRIPTION

8T (8V in transmit mode)/8R (8V in receive mode) switching and unlock circuits

In receive mode, the base of Q15,Q17 has 0.7V. As a result,Q15,Q17 is on, and Q16 and Q14 are off, then the collector of Q13 (8R) provides voltage, and the collector of Q14 (8T) provides no voltage.

The CPU output serial data to shift register IC5 when the PTT switch is depressed. As a result, pin 8 of IC5 becomes "L", turning Q17 off, and Q16 and Q14 on. The 8T line is therefore supplied with 8V. D7 is using for quickly switching of 8T.

The unlock protect circuit operates only in transmit mode. Q18 is a PLL unlocking switching transistor. Usually, the base of Q18 is supplied with 0V ("L"), and the collector is supplied with 8V ("H").

When the PLL is unlocked, the base of Q18 is supplied with 0.7V, turning Q18 on. As a result, the collector of Q18 becomes "L" (0V), this turns Q16 off and the collector of Q14 becomes 8V, turning it off. Therefore, when the PLL is unlocked. Q14 is off removing bias voltage from the 8T line. Without the 8T voltage no transmit signal is generated.

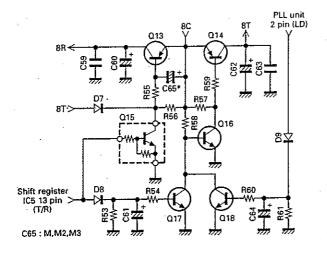


Fig. 6 8T/8R switching and unlock circuits

DIGITAL CONTROL UNIT

Overview

The digital control unit consists of a several keys, a rotary encoder input, a lamp switching circuit, a reset circuit, and a back-up circuit. These circuits are controlled by a single microprocessor (CPU).

The LCD drive and a tone output is carried by CPU.

· Key and rotary encoder input circuits

The keys (on the panel) input and output from the rotary encoder is fed directly into the CPU.

· Microphone key input circuit

The UP, DOWN, and other function keys of the microphone are directly connected to their corresponding analog input pins of the CPU. Each of the functions is activated by a voltage generated when the corresponding key is pressed.

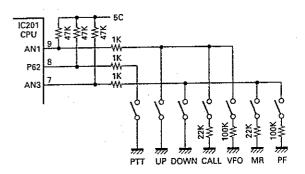


Fig. 7 Microphone key input circuit

· Lamp switch circuit

The lamp switch circuit is switched by the constant voltage of 8V from 8C with Q201 and Q202. The lamp switch circuit is turning ON and OFF to LCD back-lamp. R201 is always supply the idle-current to the lamps, it on account of prevent an over-current from flowing through the lamp.

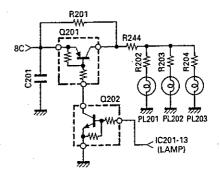


Fig. 8 Lamp switch circuit

CIRCUIT DESCRIPTION

Reset and back-up circuits

When the TM-261A power is turned on, the reset circuit sends a "L" level pulse to the RESET pin of the CPU. This initiates the power-on reset sequence.

When the TM-261A power is turned off, the back-up circuit detects a voltage drop in the SB line and sets the CPU INTO (BCHK) to a "H" level. This causes the CPU to enter a back-up state and then back-up data is transmitting to the EEPROM (IC210: X25160SI-2.7).

· Microprocessor and EEPROM

The microprocessor (IC201) and the EEPROM (IC210: X25160SI-2.7) is connected three line system of data input and output. The data forward with Serial-data type. The port P17 and P20 of the microprocessor are directly connected to SI and SO port of the EEPROM.

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Shift register circuit

The shift register circuit consists of IC5 (BU2090FS). The IC5 receives serial data from the microprocessor to perform the controls listed below.

Pin No.	Pin name	Function
1	Vss	GND
2	DATA	Serial data input
3	CLOCK	Clock input
4	AMR	Usually 'H'
5	AM1	Usually "L"
6	AM2	Usually "L"
7	AM3	Usually "H"
8.	_	Not used
9	_	Not used
10	TXM	TX power select.
		"H" in MID mode, "L" in HI or LOW mode
1,1	TXH	TX power select.
		"H" in Hi mode, "L" in MID or LOW mode
12	_	Not used
13	T/R	Transmit/receive select.
		"H" in RX mode, "L" in TX mode
14	MUTE	AF mute. "H" when TX mode, CTCSS or squelch is on.
15		Not used
16	Vdd	5V

Table 5

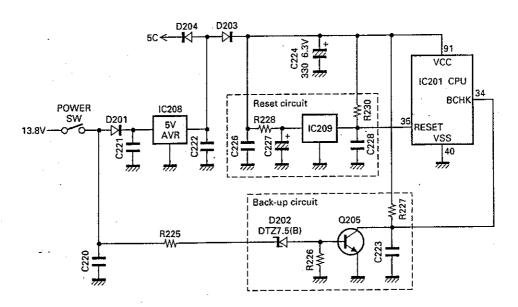


Fig. 9 Reset and back-up circuits

· PLL data output

PLL data is available from P47 (CK), P46 (DT), and P50 (EP1) of the CPU. Figure 10 is a timing chart for PLL data transfer, and Figure 11 shows the format of PLL data.

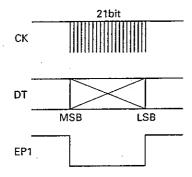
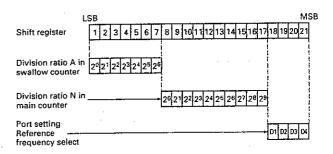


Fig. 10 Timing chart for PLL data transfer



The 21-bit data is made up of the following:

- 1. Division ratio data A and N (17bits)
 - F (Display 10.7MHz (M,M2,M3) or 30.825MHz (K) in RX mode)
- $= \{(N \times 128) + A\} \times 12.8MHz \times ref$
 - N: Division ratio set in 10-bit main counter (binary)
 - A : Division ratio set in 7-bit swallow counter (binary)

2. Reference frequency (ref) select (2bits)

Da	eta	Phase reference	
D1	D2	frequency	
L	L	5kHz	5,10,15,20,25kHz step mode
Н	H	6.25kHz	12.5kHz step mode

3. Switch select (2 bit)

Di	Data		rt port	
D3	Đ4	SW1	SW2	
L	Н	L	Н	RX mode
Н	L	Н	L	TX mode

Fig.11 PLL data format

Input and output of CTCSS unit (option)

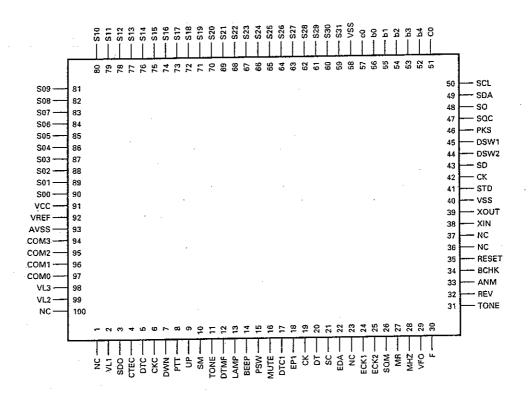
The optional CTCSS unit receives data from P64,P65, and P66 of the CPU.

When a tone from the CTCSS unit is detected, a "H" level signal is sent to P67 of the CPU, opening the squelch.

SEMICONDUCTOR DATA

CPU: M38267M8L10*FP (TX-RX Unit IC201) 3: M2,M3 4: M 5: K

· Terminal connection diagram



Terminal function

🔾 : Puil up, 🌑 : Puil up

Pin No.	Pin	1/0	P/U	Pin name	Function
1	C1	- ''-	1	-	Not used (Vss).
2	VL1	 		VL1	Power supply for LCD.
3	P67	1/0	•	P_SD0	CTCSS signal detect.
4	P66	1/0	0	P_CTEC	CTCSS connected/CTCSS enable output.
5	P65	0		P_DTC	CTCSS data output.
6	P64	10		P_CKC	CTCSS clock output.
7	AN3	- - - - 	0	P_DWN	DOWN, MR, PF.
8	P62	1	0	P_PTT	Stand-by for PLL.
9	AN1		Ō	P_UP	UP, CALL, VFO.
10	P60		<u> </u>	P_SM .	S-meter input.
11	DA2	- 		P_TONE	Sub-tone output.
12	DA1	0		P DTMF	DTMF tone output.
13	P55	- -	 	P. LAMP	Lamp control.
14	P54	0		P BEEP	Beep tone output.

SEMICONDUCTOR DATA

Pin No.	Pin	1/0	P/U	Pin name	Function
15	P53	0	1	P_PSW	Power switch.
16	P52	0		P_MUTE	MIC mute.
17	P51	0	1	P_ES1	Shift register data output.
18	P50	0	T	P_EP1	PLL IC enable output.
19	P47	0		P_CKS	PLL and shift register clock output.
20	P46	0		P_DTS	PLL data output.
21	P45	1	0	P_SC	BUSY signal input.
22 .	P40	0		P_SQM	Squelch monitor.
23	P43/TOUT	1/0			Not used.
24	INT3	t	0	P_ENCCK1	Encoder clock1.
25	INT2	1	0	P_ENCCK2	Encoder clock2.
26	R44	T	0	P_EDA	Encoder data.
27	P77	1	0	P_KEY6	VFO-key input.
28	P76	1	0	P_KEY5	MR-key input.
29 .	P75		0	P_KEY4	MHz-key input.
30	P74	ı	0	P_KEY3	F-key input.
31	P73	1	0	P_KEY2	TONE-key input.
32	P72	I	0	P_KEY1	REV-key input.
33	P71	1/0	0	P_KEU0	ID-key input.
34	INTO	1	0	BCHK	Power supply check.
35	REST	1		SET	System reset input.
36 -	XCIN				Not used (Vss).
37	XCOUT	0			Not used (Open).
38	XIN	Į.		XIN	4.19MHz crystal oscillator.
39	XOUT	0		XCOUT	4.19MHz crystal oscillator.
40	Vss	ł		Vss	GND.
41	P27	I/O	•	P_STD	DTMF signal detect.
42	P26	0		P_CKD	DTMF decoder clock line.
43	P25	0		P_SD	DTMF decoder data line.
44	P24	0		P_DTSW2	DTMF input select switch 2.
45	P23	0		P_DTSW1	DTMF input select switch 1.
46	P22	I	•	P_PKS	Packet standby.
47	P21	0		P_SQC	Squelch control.
48	P20	1		P_EPSO	EEPROM SO.
49	P17	0		P_EPDT	EEPROM SI.
50	P16	0		P_EPCK	EEPROM clock line.
51	P15	1/0	0	P_C0	Channel display bit.
52~56	P14~P10	1	0	P_B4~P_B0	Destination bit 4~0.
57	P07	0		P_EPCS	EEPROM chip select.
58	P06	1/0			Not used (Vss).
59~90	SEG31~SEG00	0		P_SEG31~P_SEG0	LCD segment 31~0.
91	Vcc	1		Vcc	Power supply pin,
92	VREF			VREF	Standard power supply for A/D converter.
93	AVss	1		AVss	Standard GND for A/D converter.
94~97	сомз~сомо	0		P_COM3~P_COM0	LCD common 3~0.
98	VL3			VL3	power supply for LCD
99	VL2	1		VL2	power supply for LCD
100	C2	1	T		Not used (Vss).

DESCRIPTION OF COMPONENTS

TX-RX Unit (X57-4970-XX) -11 : K -21 : M -22 : M2 -23 : M3

Ref. No.	Use/Function	Operation/Condition/Compatibility
IC1	2nd local oscillator, Mixer,	1 : 1st IF signal input
	IF amplification,	(10.7MHz (M,M2,M3), 30.825MHz (K))
	IDetection,	3,4 : 2nd local oscillator NOISE AMP NOISE DET AF AMP (250) HSM (250) HSM (250) HSM (250) HSM (250) HSM
	Low-frequency amplification,	(10,245MHz (M,M2,M3), 30.370MHz (K)) (88As) (88As)
	Noise amplification,	9 - Rusy output
	Noise detection,	10 : Squelch control
	Squelch switching	11 : S-meter output
		14 : RD output 국 영 및 등 표 한 법 등 등 등 등 등 등 등 등 등 등 등 등 등 등 등 등 등 등
		15 : Low-frequency output
IC2	AM detector	K type only
IC3	AF amplification	1 : AF input 6 : AF output
IC5	Shift register	See circuit description.
IC6	5V AVR	
IC7	10V-AVR	For PLL
IC8	Transmit drive	
IC9	8V AVR	
IC10	Analog switch	K type only.
IC201	Microprocessor	See circuit description.
IC205	Analog switch	
IC207	Low-frequency amplification	Mic amplifies.
IC208	5V AVR	
IC209	Reset	
IC210	EEPROM	
IC211	DTMF decoder	
IC212, 213	Analog switch	
IC213	Analog switch	
Q1	High-frequency amplification	Operates in receive mode.
Ω2	AMR switch	K type only.
Q3 ·	BPF switch	K type only.
Q4	1st mixer	Converts received 144MHz-range signals to 1st IF (10.7MHz (M,M2,M3), 30.825MHz (K)).
Q5	High-frequency amplification	Amplifies 1st (F signal.
Q6	Q5 gain control	K type only.
Ω7	Detector output switch	K type only.
Q8	Low-frequency amplification	K type only.
Q12	AF line mute	Operates when transmit mode, CTCSS or squelch is on.
Q13	8R switching	On in receive mode.
Q14	8T switching	On in transmit mode.
Q15	8R switching control	On in receive mode.
Q16	8T switching control	, 0,,,,,
Q17	8T switching control	Off in transmit mode.
Q18	8T switching control	Off when PLL locked.
Q19	Modulation system mute	On in receive mode.
Q20	PLL 8V ripple filter	i
Q21	CV line buffer	0, #
		(C5-13) Di
		3 2
		011 411 411 411 411 411
		MAX SC MIC AMP SCL SC 100 MAX OC
		Vari-cap dioda
-		# ÷ ┗━== # ÷
	1	

DESCRIPTION OF COMPONENTS

Ref. No.	Use/Function	Operation/Condition/Compatibility
Q22	VCO output amplification	
Q23	TX power select	On in MID mode.
Q24	TX power select	On in HI mode.
Q25	TX drive stage +B control	Q31 Q32 Q24 Q24
		VAIS VAIS VAIS VAIS VAIS VAIS VAIS VAIS
Ω26	Power switch	
Q27	Power switch control	On when power switch is on.
Q28	Squelch hysteresis	On when the squeich is on.
Q29	RD buffer amplification	PSW>W- POWER IC1-12 Jm POET POWER IC1-12 Jm POET POWER IC1-12 Jm POET POWER IC1-12 POWER IC
Q30~32	APC control	See circuit description.
Q33	·BPF switch	Usually off.
Q201	Lamp switch	Osdally on.
Q202	Lamp switch control	Q201
		- 0.2022
Q203	Low-frequency amplification	
Q204	Mic mute	On when DTSS code are sent. Usually off.
Q205	buffer amplifier switch	On when SB voltage is less than 7.5V. Usually on.
4		IC213 BC MIC AMP C203 MIC MIC MIC MIC MIC MIC MIC MI
D1~6	Vari-cap tuning	
D7~9	Reverse current prevention	
D10	VCO output switch	
D11	Temperature compensation	For APC,
D12, 13	Transmit/receive switching	
D14,15	Power detection	For APC.
D16	Reverse power protection	
D17	Tune switching	K type only.
D201	Reverse current prevention	
D202	Voltage drop detect	For power supply.
D203~207	Reverse current prevention	

DESCRIPTION OF COMPONENTS

PLL (X58-4390-00): M, M2, M3

Ref. No.	Use/Function	Operation/Condition/Compatibility
IC51	PLL	1 : VCO input. 133.300 to 135.295MHz (M), 125.300 to 163.295MHz (M2,M3) in receive mode, 144 to145.995MHz (M), 136 to 173.995MHz (M2,M3) in transmit mode. 11 : "L" in transmit mode. 14 : "H" when PLL unlocked.
Q1	VCO output buffer	
Q2	vco	133.300 to 135.295MHz (M), 125.300 to 163.295MHz (M2,M3) in receive mode, 144 to 145.995MHz (M), 136 to 173.995MHz (M2,M3) in transmit mode.
Q51	VCO output buffer	
Q52	Transmit switch	Off in transmit mode.
Q53	Transmit switch	On for moment when transmission stars.
Q101,102	LPF	
D1	For modulation in TX mode	
D2·	VCO voltage control	

PLL (X58-4400-00): K

Ref. No.	Use/Function	Operation/Condition/Compatibility
IC1	PLL	1: VCO input. 105.175 to 166.820MHz in receive mode, 144.000MHz to 147.995MHz in transmit mode. 11: "L" in transmit mode.
		14: "H" when PLL unlocked.
Q1,2	LPF	
Q3	Transmit switch	On for an instant when transmission starts.
Q4	VCO output buffer	
Q101	Receive VCO	107.175 to 166.820MHz.
Q102	Receive VCO switch	On in receive mode.
Q103	Receive VCO output buffer	107.175 to 166.820MHz.
Q104	Transmit VCO	144,000 to 147.995MHz.
Q105	Transmit VCO switch	On in transmit mode.
Q106	Transmit VCO output buffer	144.000 to 147.995MHz.
D101,102	VCO voltage control	Receive.
D103,104	VCO voltage control	Transmission. Varactor diode for modulation in transmit mode.

PARTS LSIT

* New Parts. A indicates safety critical components.

Parts without **Parts No.** are not supplied.
Les articles non mentionnes dans le **Parts No.** ne sont pas fournis.

Teile ohne Parts No. werden nicht geliefert.

L : Scandinavia Y: PX (Far East, Hawaii) Y: AAFES (Europe)

K: USA P : Canada E : Europe M: Other Areas T : England X: Australia

TX-RX UNIT (X57-4970-XX)

Ref. No.	Address	New parts	Parts No.	Description	Desti- nation	Ref. No.	Address	New parts	Parts No.		Descripti	On	Desti- nation
	•		TM	-261A		63		*	W01-0433-04	SPANNER	ACCESS	ORIES	
1	1B	*	A01-2115-03	METALLIC CABINET TOP METALLIC CABINET BOTTOM		A1 A1	2B,2C 2B,2C	*	X58-4390-00 X58-4400-00	SUB UNITPL			M,M2M3 K
2 3	28 2A	*	A01-2116-03 A62-0456-03	PANEL ASSY			L	<u></u>		<u> </u>			<u> </u>
5	1B,1C		B42-2455-04	STICKER (M4X8 MAX)				<u> </u>	(57-4970-XX)		21 : M	-22 : M2	-23 : M3
9		*	846-0469-00	WARRNTY CARD INSTRUCTION MANUAL (ENGLISH)	K	65 66	2B 2B	*	B11-1154-02 B11-1156-04	REFLECTOR			
12 12		*	B62-0605-00 B62-0606-00	INSTRUCTION MANUAL (SPANISH)	к,мз	LCD	2A	*	B38-0761-05	LCD			
13	1C	*	B72-1041-04	MODEL NAME PLATE	K	PL201-203		*	B30-2158-05	LAMP			
13	1C	*	B72-1042-04	MODEL NAME PLATE	M2,M3	C1			CC73FCH1H040C	CHIP C	4.0PF	C	
13	1C .	*	B72-1043-04	MODEL NAME PLATE:	M	C3	-	-	CC73FCH1H180J	CHIP C	18PF	J K	
				LOGSONONY		C4-7			CK73FB1H102K CK73FB1H102K	CHIP C	1000PF 1000PF	K	K M,M2M3
15			E30-2111-15	DC CORD ACCESSORY		C6.7 C8		ļ	CK73FB1H102K	CHIP C	0.010UF	K.	IVI,IVIZIVIG
16	1C		E30-2137-15	DC CORD - ANTENNA CORD		L8		1	CK/3FB1R1U3K	CHIE C	0.01001	K	
17	1C		E30-2145-15	LEAD WIRE WITH CONNECTOR	{	C9			CK73FB1H102K	CHIP C	1000PF	K	
18	1B		E31-3197-15	CEND WASE WITH COMMEDIUM		C10		1	CC73FCH1H0R5C	CHIP C	0.5PF	C	
21	2A	*	F15-0695-04	SHADE PLATE		C11			CC73FCH1H27OJ	CHIP C	27PF	J	
22 ·	2B	*	F15-0696-04	SHADE		C12		1	CK73FB1H103K	CHIP C	0.010UF	K	
24	1C	"	F51-0013-05	FUSE 4A	м	C13	}		CC73FCH1H0R5C	CHIP C	0.5PF	С	
24	1C		F51-0017-05	FUSE 15A	K,M2M3	1							
25	, ,		F51-0018-05	FUSE 20A ACCESSORY		C14			CC73FCH1H270J	CHIP C	27PF	J	
-				İ		C15	ĺ		CK73FB1H102K	CHIP C	1000PF	K ·	
29	28	*	G02-0794-04	FLAT SPRING GND		C16			CC73FCH1H150J	CHIP C	15PF	J	
30	2C	*	G02-0795-04	FLAT SPRING GND	[C17	i	1	CC73FCH1H270J	CHIP C	27PF	J	K.M
31	1B	*	G02-0796-04	FLAT SPRING IC	ì .	C18	· ·		CK73FB1H103K	CHIP C	0.010UF	K	
35	1B,2C	*	G10-0779-04	FIBROUS SHEET CHASSIS		1		i :					
37	1C	*	G10-0786-04	FIBROUS SHEET SP HOLDER		C19			CC73FCH1H030C	CHIP C	3.0PF	C	
		i				C20			CK73FB1H102K	CHIP C	1000PF	K	
38	2B	*	G13-1539-04	CUSHION]	C21			CK73FB1H103K	CHIP C	0.010UF	K	.
			609-0405-05	KNOB SPRING	İ	C22 C23			CK73FB1H102K CC73FCH1H050C	CHIP C	1000PF 5.0PF	K C	M,M2M3
10		*	H52-0763-02	ITEM CARTON CASE	K,M2M3	1020		1					
10			H52-0764-02	ITEM CARTON CASE	М	C23		i	CC73FCH1H080D	CHIP C	8.0PF	D	K
11	1		H10-6601-02	POLYSTYRENE FOAMED FIXTURE	[C24			CK73FB1H102K	CHIP C	1000PF	K	
12	1	- 1	H11-0885-04	POLYSTYRENE FOAMED BOARD		C25			CK73FB1H103K	CHIP C	0.010UF	K	
13		*	H13-0977-04	CARTON BOARD		C26			CC73FCH1H100D	CHIP C	10PF	D	K
	İ		Unc 0100 04	PROTECTION BAG 125X250 DC CORD		C26			CC73FCH1H220J	CHIP C	22PF	J	M2,M3
4			H25-0103-04 H25-0337-04	PROTECTION BAG 125X250 DC CORD		C26			CC73FCH1H470J	CHIP C	47PF	J	м
15			H25-0337-04 H25-0720-04	PROTECTION BAG 180X300 ITEM		C27			CK73FB1H102K	CHIP C	1000PF	K	1
6	-		1125-0720-04	THOTEOTICIN DAG TOURSON TIEM		C28			CC73FCH1H100D	CHIP C	10PF	D	κ
io	1C	*	J19-1580-04	HOLDER SPEAKER		C28			CC73FCH1H330J	CHIP C	33PF	J	M,M2M3
ii			J29-0628-03	BRACKET ACCESSORY	. [C29			CC73FCH1H151J	CHIP C	150PF	J	M,M2M3
i5	1A	*	K27-3163-04	KNOB POWER		C29,30			CK73FB1H102K	CHIP C	1000PF	K	ĸ
6	1A	r	K29-5090-04	KNOB MAIN		C31			CC73FSL1H101J	CHIP C	100PF	J	ĸ
7	1A		K29-5091-04	KNOB VOLUME		C32			CED4EW1C100M	ELECTRO	10UF	16WV	
ĺ						C33			CK73FB1H223K	CHIP C	0.022UF	K	K
·	1C,2C	3	N33-2606-45	OVAL HEAD MACHIN SCREW		C34			CK73FB1H333K	CHIP C	0.033UF	K	K
	2A		N38-2640-46	PAN HEAD MACHINE SCREW					000 0004 65	CUID TAN	1 01 15	101687	v
	28		N67-3008-45	PAN HEAD SEMS SCREW		C35		[C92-0004-05	CHIP-TAN CHIP C	1.0UF 0.010UF	16WV K	K
'	2B,2C		N87-2606-46	BRAZIER HEAD TAPTITE SCREW		C36,37			CK73FB1H103K C92-0002-05	CHIP-TAN	0.010Gr 0.22UF	35WV	ĸ
		- 1	N99-0331-05	SCREW SET		C38			C92-0002-05 C92-0003-05	CHIP-TAN	0.47UF	25WV	M
,		- 1.	TO1 0616 05	***CDODUONE	M,M2	C38			C92-0504-05	CHIP-TAN	0.470f	20WV	M2,M3
1A	. [T91-0516-05	MICROPHONE MICROPHONE	к,м2 К,М3	Ç30			00E V00T 00	J. 17311	2.0301		
1A]		T91-0568-05	INICHOEFICIYE	N,IVIJ	C39			CK73FF1C105Z	CHIP C	1.0UF	Z	K
,	J	- ,	E30-3206-08	CURL CABLE MIC	M,M2	C41			CK73FF1C105Z	CHIP C	1.0UF	Z	
1B 1B		1	E30-3200-08	CURL CABLE MIC	K,M3	C43		[CE04EW1A470M	ELECTRO	47UF	10WV	
''	- 1	- ['	LUU-UZ40-00	SOME OFFICE INIO	,	C44			CK73FB1H103K	CHIP C	0.010UF	K	
Р .	1B	*	T07-0331-05	LOUDSPEAKER (FULLRANGE)		C47			CK73FB1E104K	CHIP C	0.10UF	K	1
	יטי	т	107 70001-00	EUODOI ENKEITYI OECIINIYOO)									L

PARTS LIST

Park No. Modes Park No. P						_				·			····	IX-KX	OMIT (X	57-4970-XX
Description of the component of the co	Ref. No.	Address		Parts No.		Descripti	on		Ref. No.	Address		Parts No.				
Comparison	C40	+	puits	CCCAEVALLA A 71 MA	ELECTRO	470UF	10WV	1	C116		İ	CC73FCH1H0R5C	1 *			
Comparing Comp	-	ĺ						1 1	C116		ł	CC73FCH1H010C				M
Comparison Com					1			l i	C117			CC73FCH1H020C	1			
Comparison								- I - I	C118			CM73F2H270J	t			
Comparison Com								:	C118			CM73F2H470J	CHIPC	47 P F	J	K,M2M3
Section	C33			020121110101111								CA35CD111103N	CLIBC	1000PF	ĸ	
Commonweight Comm	C54			CK73FB1H473K	CHIP C	0.047UF			4		1		1			4
Composition Composition				CK73F81H681K	CHIP C	680PF	K		1		1		1			i
COMPRINES ORDER	C56			CE04EW1C470M	ELECTRO	47UF					1	-	1			1
COMPRISENDED CONTROLLED C				CK73FF1C105Z	CHIP C	1.0UF	Z	·}			{					M2 M3
CONTROLLAND CONTROLLAND	C58,59				CHIP C	0.910UF	K		C124			CC73FCH1H120J	CHIP	IZFr	J	1412,1413
CONTROLLED CON				0004014414141014	CLECTOR	471 IC	10\AA/	}	C124			CC73FCH1H270J	CHIP C	27PF		1 **
COLUMN C					1							CM73F2H050D	CHIP C	5.0PF		K,M2M3
Comparison Com					1			1 1		1		CM73F2H060D	CHIP C	6.0PF	D	
Company								1 1		1	1	CM73F2H150J	CHIP C	15PF	J	
CORRECTION SECTION S		1			1			1 1		1		CC73FCH1H270J	CHIP C	27 P F	J	K
COMPANY CONTROL CONT	C64			C92-0504-05	CAIT-IAIN	0.0001	20111		.						_	
Comparison	Ces			CF04FW1C470M	ELECTRO	47UF	16WV	M,M2M3	4			1				
Comparison Com						15PF	J		C132	Ι.		1				1
CC25981HH02K CHIP C						22PF	J									1
CC39FCH1683U					1	0.010UF	K			1			1 '			
CK78FBH102K CK78FBH102K CHP C 0.047UF K C138 C138 CK78FBH102K CK78FBH102K CHP C 1000FF K C138 C138 CK78FBH102K CHP C 1000FF K C141,142 CK78FBH102K CHP C 0.000FF K C201 CK78FBH102K CHP C 0.000FF K C201 CK78FBH102K CHP C 0.000FF K C201 CK78FBH102K CHP C 0.000FF K C201 CK78FBH102K CHP C 0.000FF K C202 CK78FBH102K CHP C 0.000FF K C203 CK78FBH102K CHP C 0.000FF K C203 CK78FBH102K CHP C 0.000FF K C204 CK78FBH102K CHP C 0.000FF K C204 CK78FBH102K CHP C 0.000FF K C204 CK78FBH102K CHP C 0.000FF K C205 CK78FBH102K CHP C	C70				1	39PF	j	K	C135			CK73FB1H102K	CHIPC	100026	K	
C72 CX7581H102K CRP C C CRP C C CRP C	•								C129			CEN4EW1E4B7M	ELECTRO	4.7UF	25WV	-
C73	C72	i	1		1 -				1			1		1000PF	K	1
C75	C73	1	1	l									1		C	k
C73FG	C74		1	1 '						1	ļ	1 '	1 '			
C736	C75			*****	1			1 1		1	i	1 -				
C739	C76			CK73FB1H102K	CHIP C	1000PF	K		6201			GRASIOTINOZA				
CC73FG1H103K CHIP C	030			CV73E91H103V	CHIEC	1000PF	К		C202			CK73FF1C105Z	1 -			1
CR79FB1H102K CHP C				l	3				C203			CK73FB1H102K	1			ļ
CC73FCH1H220_J CHP C		1	1	l					C204		1	CC73FCH1H101J	•		-	
CRAPT CRAP					4				C205	1	1	CE04CW1C100M	1			1 .
CGAPWIAA7BM CCAPPENIAA7BM	C82				4				C206			CC73FCH1H820J	CHIPC	82PF	J	
CRIT CRIT						471.15	10\45/		C207		1	CK73F81H332K	CHIP C	3300PF	K	
CRAPTION CRAPTION	C83		1	t .								II .	CHIP C	680PF	K	
CEMEMYTICINOM CREATED TOUR TOWN CREATED TOWN CREATED	C84]	1				1 1		1 .		II .	CHIP C	0.033UF	K	
CRYSFB1H102K CHIP C CHIP			ł									II .	CHIP C	27PF	J	-
CRASS CRASSESSISTED CRAS					l l						1	1	CHIP-TAN	1.0UF	16WV	
CR34 CR36PH103K CHIP C D.010UF K C212 C213 CR36PH102K CHIP C D.010UF K C214 C214 C214 C214 C215PH102K CHIP C D.010UF C214 C214 C215PH102K CHIP C D.010UF C214 C215PH102K CHIP C D.010UF C216PH102K CHIP C D.010UF C226PH102K C216PH102K CHIP C D.010UF C227PH102K	L89-92		1	CKARBITTOZK	0	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,				1		OV. TOPE A L SOCIAL	cun c	0.023116	v	.
CEMENTARYON	C93			CK73FB1H103K	CHIP C	0.010UF					1					
C35.96 C37	C94] .	CE04EW1A470M	ELECTRO	47UF	10WV	}		1	1	1 .	4			
CEMARWICIDIZAM CEECTRO 1000UF 15WV C216,217 C218 C275FCH1HI01J CHIP C 1000F J C216,217 C275FCH1HI01J CHIP C 1000F J C275FCH1HI01J CHIP C 1000F J C275FCH1HI01J CHIP C 1000F J C275FCH1HI01J CHIP C 1000F J C275FCH1HI01J CHIP C 1000F J C275FCH1HI01J CHIP C 1000F K C275FCH1HI01J CHIP C 0.010UF K C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.000F J C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.010UF C775FCH1HI01J CHIP C 0.	C95,96		1	CK73FB1H103K	CHIP C	-				1	1					
CR73FB1H102K	C97			CE04EW1C102M	-				1 1	1						
CR73F61H102K	C99	Ì		CK73FB1H102K	CHIPC	1000PF	K		UZ16,217		Į	CC/3/GITTITO	G/11 G	100.7	•	
Citol	0100	1		CM33661 C1067	CHIPC	1 OUE	7		C218			CK73F81H102K	CHIP C			
C102	1				l l			1	C219	1		CK73FB1H103K	1			
C104	1				l l				C220,221		ļ	CK73FB1H102K				
C104		}		1				м	C222,223		1	CK73FB1H103K	II.			1
C105			*	1				K,M2M3	C224			CE04CW0J331M	ELECTRO	330UF	6.3WV	
C105 CHIP C TOUPF K CHIP C TOUPF K CATSFB1H102K CHIP C TOUPF K CHIP C TOUPF K CATSFB1H102K CHIP C TOUPF C TOUPF C TOUPF	0.0.			1					0005			CE04C/A/1C100M	ELECTRO.	10UE	16WV	
C106	C105								1 1		}					
C107	C106	1		CC73FCH1H220J							1					-
C107	C107		*	1 -				-					1			
C108 C108 CM73F2H380J CHIP C 33PF J M C232 CC73FCH1H0R5C CHIP C 0.5PF C K,M2M3 C109 CC73FCH1H010C CHIP C 1.0PF C M C236 CC73FCH1H010C CHIP C 2.0PF C M C237 C110 C110 C110 C110 C111-113 C114 * C91-3025-05 CHIP C 39PF J M C244 C114 * C91-3025-05 CHIP C 39PF J M C244 C116 C174 C174 C174 C174 C174 C174 C174 C174	C107		*	1	L				3 I			1				
C108 C109 C109 C109 C100 C100 C100 C100 C100	C108			CM73F2H180J	CHIP C	18PF	J	K,MZM3	0231			, Chronostinen				
Club Club CC73FCH1H0R5C CHIP C 0.5PF C CC73FCH1H010C CHIP C 0.010UF K CC73FCH1H010C CHIP C 0.010UF CC73FCH1H010C CHIP C 0.010UF CC73FCH1H010C CHIP C 0.010UF CC73FCH1H020C CHIP C 0.010UF CC73FCH1H030C CHIP C 0.010UF CC73FCH1H030C CHIP C 0.010UF CC73FCH1H030C CHIP C 0.010UF CC73FCH1H101J CHIP C 0.01	0.00			C\$479E9H990	Critio C	3355	.l	м	C232			CC73FCH1H330J	CHIP C			
Clop		Ì	1							-		CK73F81H103K	CHIP C			ļ
C109				1				1 -	, i · ·	1		CK73FB1H332K	CHIP C	3300PF		
C110 C110 C110 CC73FCH1H030C CHIP C 3.0FF C K.M2M3 C238-241 CC73FCH1H010J CHIP C 100PF J CC73FCH1H010J CHIP C 100PF J CC73FCH1H010L CHIP C 100PF J CC73FCH1H010L CC73FCH1H010L CHIP C 100PF J CK73FB1H102K CHIP C 100PF J CC244 CC73FCH1H101J CHIP C 100PF J CC745 CC73FCH1H101J CHIP C 100PF J CC745 CC73FCH1H101J CHIP C 0.010UF K CC745 CC73FCH1H101J CHIP C 100PF J CC745 CC73FCH1H101J CHIP C 100PF J CC745 CC73FCH1H101J CHIP C 100PF J CC745 CC73FCH1H101J CHIP C 100PF J CC745 CC73FCH1H101J CHIP C 100PF J CC745 CC73FCH1H101J CHIP C 100PF J CC745 CC73FCH1H101J CHIP C 100PF J CC745 CC73FCH1H101J CHIP C 100PF J					l l			l l			ļ	1	CHIP C	0.10UF	Z	
C111-113 CK73FB1H102K CHIP C		1	1					5	1 I		1	 	CHIP. C	100PF	J	ļ
C111-113 CK73FB1H102K CHIP C 1000F K C242 CC73FCH1H101J CHIP C 100PF J C114 * C91-3029-05 CHIP C 56PF J M C244 CX73FF1E104Z CK73FF1E104Z CK73FB1H102K CHIP C 1000PF K C745 CK73FB1H102K CHIP C 1000PF K CX73FB1H102K CX73FB	C1 10		1	CG/3FCRTHU30G	GRIF	3.01 ₹	•									
C114 * C91-3025-05 CHIP C 39PF J K,M2M3 C243 CC73FCH1H1013 CHIP C 100FF J M C244 C73FF1E104Z CHIP C 0.10UF Z CK73FF1E104Z CHIP C 1000PF K	C111-113			CK73FB1H102K	CHIP C	1000PF	K					1	1			
C114 * C91-3029-05 CHIP C 56PF J M C244 CK73FF1E104Z CHIP C 0.100PF K			*	1	CHIP C	39PF	j					1 '				İ
1 1 1 1 1 1 1 1 1 1			1		CHIP C	56PF	J _	М		Į			1			
			1	1 '				1	C245		ļ	CK73FB1H102K	CHIPC	100021	Ν	

PARTS LSIT

Ref. No.	Address	New parts	Parts No.	Description	Desti- nation	Ref. No.		New parts	Parts No.		Desc	riptio	П	Desti- nation
C246,247			CC73FCH1H100D	CHIP C 10PF D		R19			R92-0670-05	CHIP R	O OHM			M,M2M3
C248	1		CK73FB1H102K	CHIP C 1000PF K	i	R20			FK73FB2A101J	CHIP R	100	J	1/10W	
C249	ĺ	ļ	CK73FB1H103K	CHIP C 0.010UF K		R21			RK73FB2A471J	CHIP R	470	J	1/10W	
C250		}	CK73FF1C105Z	CHIP C 1.0UF Z		H22	1		RK73FB2A152J	CHIP R	1.5K	J	1/10W	м,мама
C251,252			CK73FB1H472K	CHIP C 4700PF K		R23			RK73FB2A102J	CHIP 8	1.0K	Ĵ	1/10W	K
TC1			C05-0349-05	TRIM CAP 10P	İ	R23			RK73FB2A471J	CHIP R	470	J	1/10W	M,M2M3
					1 1	R24			RK73FB2A101J	CHIP R	100	J	1/10W	
CN1			E40-3237-05	PIN ASSY] [R25	1 1		RK73F82A103J	CHIP R	10K	J	1/10W	
CN3.4		*	E40-5817-05	PIN ASSY		R26	1 1	- 1	RK73FB2A473J	CHIP R	47K	J	1/10W	
CN201,202			E40-5203-05	PIN ASSY SOCKET	1 1	R27	1	- 1	RK73FB2A272J	CHIP R	2.7K	Ĵ	1/10W	K
CN203		*	E40-5830-05	FLAT CABLE CONNECTOR		1		ı						1"
J1 .		•	E11-0425-05	PHONE JACK	ļ	R28		1	RK73FB2A103J	CHIP R	10K	J	1/10W	1
J1		,	C17-0425-05	Troite droit	} {	R29		.	RK73F82A681J	CHIP R	680	Ĵ	1/10W	k
J201			E08-0877-05	RECTANGULAR RECEPTACLE		R30			RK73FB2A103J	CHIP R	10K	J	1/10W	ľĸ
W1,2			E33-1871-25	PROCESSED WIRE KIT	ĸ	R30]	RK73FB2A153J	CHIP B	15K	Ĵ	1/10W	M,M2M3
VV 1,Z			235-1071-23	THOCEGOED WITE KIT	"	R31		ļ	RK73FB2A274J	CHIP R	270K	J	1/10W	K
- 1			J30-0564-05	SPACER				ĺ	-					
	1	i			1. 1	R32			RK73FB2A332J	CHIP R	3.3K	J	1/10W	. K
CD1			L79-1013-05	TUNING COIL 455kHz	l	R33			RK73FB2A102J	CHIP R	1.0K	J	1/10W	Κ .
CF1			L72-0366-05	CERAMIC FILTER 455kHz	l i	R35	[]	1	RK73FB2A102J	CHIP R	1.0K	J	1/10W 1	· ·
L1-4			L34-4080-05	COIL		R39		- 1	R92-0670-05	CHIP R	0 OHM			M,M2M3
L5	ļ	- 1	L34-4113-05	COIL]]	R42			RK73FB2A101J	CHIP R	100	J	1/10W	
L6	- 1	Ì	L30-0005-05	COIL	M,M2M3			i.						
	l	.		l .		R43			RK73FB2A4R7J	CHIP R	4.7	J	1/10W	1
L6]		L34-2157-05	COIL	lk l	R44			RK73FB2A101J	CHIP R	100	J	1/10W	ĺ
17	1		140-1005-48	SMALL FIXED INDUCTOR 10UH	1 1	R45	i		R92-0670-05	CHIP R	0 OHM			
L8	1	-	L34-1239-05	AIR-CORE COIL 10.5T		R46			RK73FB2A102J	CHIP R	1.0K	J	1/10W	
.9	İ	1	L34-0895-05	AIR-CORE COIL 6T	ļ	B47			RK73FB2A473J	CHIP R	47K	J	1/10W	
10			L34-0742-05	AIR-CORE COIL 5T										
						848			RK73FB2A333J	CHIP R	33K	J	1/10W	
11	- 1		£34-0908-05	AIR-CORE COIL 9.5T	1 1	R49			R92-0670-05	CHIP R	0 OHM			
.12,13			L34-0499-05	AIR-CORE COIL 4T	}	R53			RK73FB2A334J	CHIP R	330K	J	1/30W	
14]		L40-3395-48	SMALL FIXED INDUCTOR 3.3UH]	R54			RK73FB2A223J	CHIP R	22K	J	1/10W	1
.15	i		L34-0499-05	AIR-CORE COIL 4T	}	R55		1	RK73FB2A182J	CHIP R	1.8K	j	1/10W	
.16	- 1]	£40-1095-48	SMALL FIXED INDUCTOR 10UH	ĸ									İ
						R56-58			RK73F82A103J	CHIPR	10K	J	1/10W	
17		ŀ	L40-1892-19	SMALL FIXED INDUCTOR 1.8UH	K	R59			RK73FB2A182J	CHIP R	1.8K	J	1/10W	
.18]		L40-4785-48	SMALL FIXED INDUCTOR 470nH	1	R60			RK73FB2A223J	CHIP R	22K	J	1/10W	
.201	Ì		L40-1091-42	SMALL FIXED INDUCTOR 1.0UH	ĺĺ	R61	1		rk73fB2A473J	CHIP R	47K	j	1/10W	
(1	1	- }	L77-1312-05	CRYSTAL RESONATOR 30.369MHz	K	R69		· [rk73fb2A224J	CHIP R-	220K	J	1/10W	
(1		ı	L77-1473-05	CRYSTAL RESONATOR 10.2441MHz	M,M2M3			- 1						
ĺ	- 1					R70	.		RK73F82A104J	CHIP R	100K	j	1/10W	
(2 .	- 1	-	L77-1405-05	CRYSTAL RESONATOR 12.800MHz	1	R72			RK73FB2A103J	CHIP R	10K	J	1/10W	
201	- 1		L77-1476-05	CRYSTAL RESONATOR 4.194304MHz		R73	ľ		RK73FB2A153J	CHIP R	15K	J	1/10W	1
(F1		- 1	L71-0228-15	MCF 10.700MHz	M,M2M3	R75-78	ł	- 1	RK73FB2A472J	CHIP R	4.7K	J	1/10W	
(F1			L71-0270-05 .	MCF 30.825MHz	K	R79			RK73FB2A105J	CHIP R	1.0M	J	1/10W	Ì
.P1	-		R90-0714-05	MULTI-COMP 10K X 4	.	R80		Ì,	RK73FB2A104J	CHIP R	100K	J	1/10W	
	- 1			MULTI-COMP 100K X 4		R81	ĺ		RK73F82A471J	CHIP R	470	Ĵ	1/10W	
P3,4	ł		R90-0714-05	MULTI-COMP 10K X 4	- 1	A82			RK73FB2A220J	CHIP R	22	j	1/10W	
				CHIPR 100K J 1/10W	1	R84			RK73FB2A122J	CHIP R	1.2K	j	1/10W	
1 2			RK73FB2A103J	CHIPR 10K J 1/10W	M,M2M3	R85			RK73FB2A220J	CHIP R	22	j	1/10W	
_	Ì													
2	- 1		R92-0670-05	CHIPR 0 OHM	K	R86	- 1		RK73FB2A223J	CHIP R	22K	J	1/10W	
3		į.	RK73FB2A274J	CHIPR 270K J 1/10W	M,M2M3	987 [RK73F82A103J	CHIP R	10K	J	1/10W	
4	- 1	- [1	RK73F82A101J	CHIPR 100 J 1/10W	- 1	R88,89			9K73F82A101J	CHIP R	100	J	1/10W	1
5		- 10	RK73F82A103J	CHIPR 10K J 1/10W	1.	R90	1	- 1	RK73FB2A102J	CHIP R	1.0K	J	1/10W	1
6		1	RK73FB2A101J	CHIPR 100 J 1/10W		R91		- [1	RK73FB2A470J	CHIP R	47	J	1/10W	
_		1.	Washer to the second	0.000	j	1000		Ι.	DV70FD0A1041	CUID D	1000	ſ	1 /50\4/	ľ
7	Į	- 1		CHIP R 100K J 1/10W	_	R92			RK73FB2A104J	CHIP R	100K	J	1/10W	_v
В	Í	- 1		•	K j	R93			RK73FB2A102J	CHIP R	1,0K	J	1/10W	K
9-11	, [i	CHIPR 100K J 1/10W	- 1	R94		1	RK73FB2A220J	CHIP R	22	J	1/10W	l.,
12,13		- 1		CHIPR 47K J 1/10W	- 1	R95	1	t	RK73FB2A104J	CHIP R	100K	J	1/10W	M
14		F	RK73FB2A470J	CHIP R 47 J 1/10W		R95		1	RK73FB2A392J	CHiP R	3.9K	J	1/10W	K,M2M3
15		,	RK73FB2A274J	CHIP R 270K J 1/10W	м,м2м3	R95			RK73FB2A103J	CHIP R	10K	j	1/10W	
16				CHIPR 47 J 1/10W	,	R97			192-1215-05	CHIP R	470	į	1/2W	1
]			CHIPR 10K J 1/10W		R98]	,	RK73FB2A103J	CHIP R	10K	j	1/10W	İ.
17 18		- 1				R99	1	•	K73FB2A271J	CHIP R-	270	J	1/10W	м
		15	RK73F82A102J	CHIP R 1.0K J 1/10W		,,,,,,		- [[my or oznar id	J. ,,, (F	2.0	-	.,	1

PARTS LIST

															TX-R	X UNIT (X	57-4970	-XX}
r		T-11	New		 	Descri	ntine		Desti-	Ref. No.	Address	New	Parts No.		Descripti	០ព	Des	
- 1	Ref. No.	Address	parts	Parts No.	_	Descri	prior		nation	<u> </u>		parts	RK73F82A473J	CHIP R	-47K J	1/10W	1	
В	3100			RK73FB2A180J	CHIP R		J	1/10W	M	R237			RK73FB2A392J	CHIP R	3.9K J	1/10W	K,M2	M3
l I	100			R92-0670-05	CHIP B	MHO 0			K,M2M3	R238	!		RK73FB2A563J	CHIP R	56K J	1/10W	M	
- 1	3101			RK73FB2A271J	CHIP R	270	J	1/10W	M	R238	}		RK73FB2A183J	CHIP R	1BK J	1/10W		ļ
	3102			R92-0685-05	CHIP R	22	j	1/2W	K.M2M3	R239				CHIP R	47K J	1/10W	1	- 1
- 1	3102			.R92-0686-05	CHIP 8	33	J	1/2W	M	R240	1	1	RK73F82A473J	LOTAL II	771. 4	17.011		
- 1									i				DOD 0070 DE	CHIP R	MHO 0		Į.	
- 10	3103			R92-1213-05	CHIPR	100	J	1/2W	K,M2M3	R244			R92-0670-05	CHIP R	0 OHM		K	
- 1	3103			R92-1214-05	CHIP R	120	J	1/2W	M I	R245			R92-0670-05	CHIP R	47K J	1/10W	1"	
	1104,105			RK73FB2A223J	CHIP B	22K	J	1/10W		R246-248	Ì		RK73FB2A473J		8.2K J	1/10W		- 1
- 1	1106			RK73FB2A274J	CHIP R	270K	J	1/10W	M2,M3	R249	1	}	RK73FB2A822J	CHIP R		1/10W		l
	1106 1106			RK73FB2A394J	CHIP R	390K	J	1/10W	M	R250-253		1	RK73F8ZA10ZJ	CHIP R	1.0K J	171011	- [
l,	1100	ļ		11117070010010						1				0.00	33 J	1/10W		- 1
l.	3107			RK73FB2A104J	CHIP R	100K	J	1/10W		- R254			RK73FB2A330J	CHIP R	-	1/10W		1
	1107			R92-0670-05	CHIP R	0 OHM			М	R255			RK73FB2A102J	CHIP R		1/10W		1
	1100 1109	1		RK73FB2A103J	CHIP R		J	1/10W		R256			RK73FB2A473J	CHIP R	47K J		-	
- 1		}		R92-0670-05	CHIP R	0 OHM			1 1	R257	ŀ	1	RK73F82A474J	CHIP R	470K J	1/10W	Ì	- 1
	R110			RK73FB2A101J	CHIP R		J	1/10W		R258	ĺ	1	R92-0670-05	CHIP R	0 OHM			- 1
- 1'	3111	1		INCOS DECTOR	•••••					ì		1			4 T/2	1 (10)	1	1
ı,	2112	1		RK73FB2A104J	CHIP R	100K	J	1/10W		Я259			RK73FB2A472J	CHIP R	4.7K J	1/10W		- 1
1	1112	1		RK73FB2A683J	CHIP R	68K	J	1/10W		R260 ·	1		RK73F82A103J	CHIP R	10K J	1/10W		- [
	3113	1		RK73F82A151J	CHIP R	150	j	1/10W		R261			R92-0670-05	CHIP R	0 OHM	1 (1014)		1
	3114 3115	1		RK73F82A154J	CHIP R	150K	Ĵ	1/10W		R262-264	ĺ		RK73FB2A473J	CHIP R	47K J	1/10W		.
	R115	1	ĺ	RK73FB2A332J	CHIP R	3.3K	J	1/10W].]	R265	1		R92-0670-05	CHIP R	0 OHM			1
- {'	R116			TACTOL DEMOSES	\\ \tag{\tag{\tag{\tag{\tag{\tag{\tag{	0.01.	-				1	1		1 .		4 140144		- 1
- 1.	2117	1	١.	RK73FB2A102J	CHIP R	1.0K	J	1/10W		R266		İ	RK73FB2A473J	CHIP R	47K J		1	
	3117			l	CHIP R	1.5K	j	1/10W		R267,268			RK73FB2A102J	CHIP 8	1.0K J	-		1
	R118		Į	RK73FB2A152J	CHIP R	10K	Ĵ	1/10W		R269			RK73FB2A223J	CHIP R	22K J		ļ	ĺ
	R119,120		1	RK73FB2A103J	CHIPR	1.5K	J	1/10W		R270-272	1	1	RK73FB2A473J	CHIP R	47K J	1/10W	1	
- 4	R121	1	i ·	RK73FB2A152J	CHIP R	2.2K	j	1/10W	}	R273		1.	R92-0670-05	CHIP R	0 OHM			1
- 11	R122			RK73FB2A222J	Chir h	2.21	-	.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		1	1						ļ	
ı		ì		0144450014001	CHIP R	1.0K	J	1/10W		R280			RD148B2C473J	RO	47K J	1/6W	Ì	
	R123			RK73FB2A102J	-	47K	J	1/10W	Ŕ	VR1	İ		R12-6746-05	TRIM POT	100K			l
	R124			RK73FB2A473J	CHIP R		J	1/10W	ĸ	VR3	1		R12-6744-05	 TRIM POT 	47K		-	
	R125,126		1	RK73FB2A472J	CHIP R	4.7K	J	1/10W	ĸ	VR4	1		R12-6740-05	TRIM PO	f 10K		1	
	R127			RK73FB2A222J	CHIP R	2.2K			ľĸ	VR5			R12-6740-05	TRIM POT	f 10K		K,M:	2M3
- 1	R128		1	RK73FB2A102J	CHIP R	1.0K	J	1/10W		''''		1					1	
		1			01110 0	ank		1/10W		VR5	ļ	İ	R12-6744-05	TRIM PO	T 47K		М	
	R200	1		RK73FB2A333J	CHIP R	33K	J	-	ļ	VR201			R05-4420-05	VARIABLI	E RESISTOR 5	iok		
- (R201	1		R92-0686-05	CHIP R	33	J	1/2W		VR202	1		R05-3441-05	VARIABLE	E RESISTOR 1	0K	1	
[R203-204	i		RK73FB2A100J	CHIP R	10	J	1/10W	1	1 1 111202		-						
	R205			RK73FB2A332J	CHIP R	3.3K	J	1/10W		S201		*	S68-0410-05	PUSH SV	VITCH			
	R206		1] RK73FB2A101J	CHIP R	100	j	1/10W		S202-208	1		\$70-0439-05	TACT SW	/ITCH		1	
								4 (4.004)	}	S202-200			W02-1707-05	ROTARY	ENCODER			
ı	R207			RK73FB2A103J	CHIP R	10K	J	1/10W	1	3203		Ì	1102 1101 11	1			- 1	
j	R208-210	1	}	RK73FB2A823J	CHIP R	82K	J	1/10W			-	*	1SV270	VARI-CA	P DIQOÉ			
J	R211	1	į	RK73FB2A473J	CHIP R	47K	J	1/10W	1	D1 D2-4		"	1SV269	VARI-CA			-	
	R212			RK73FB2A224J	CHIP R	220K	J	1/10W	1	D2-4 D5,6		*	HVU363A	DIODE				
٠	R213			RK73F82A333J	CHIP R	33K	J	1/10W		D7	ļ		MA110	DIODE			M,N	42M3
- 1				ļ	1			1 (10)11	1	08,9	ĺ		DANZ02K	DIODE			1	
I	R214	1		RK73FB2A184J	CHIP R	180K	J	1/10W		00,3		İ		}			ļ	
1	R215		1	RK73FB2A394J	CHIP 8	390K	J	1/10W		D10	1		DAN235K	DIODE	,			
	R216	1		RK73FB2A224J	CHIP R	220K	J.	1/10W		D10			DAN202K	DIODE		•	Į	
- 1	R217			RK73FB2A561J	CHIP R	560	j	1/10W	ĺ	1012		1	MI407	DIOCE			K,N	/2M3
	8218	1	1	RK73FB2A564J	CHIP R	560K	J	1/10W		1 1 '			M:308	DIODE			М	
i		1	1		1					D12,13	1	-	MI308	DIODE			K,A	/2M3
	R219	-		RK73FB2A561J	CHIP R	560	J.	1/10W	ļ	D13		1		1				
	R220	1		RK73FB2A470J	CHIP R	47	J	1/10W	1	014.5			1SS226	DIODE			1	•
	R221	1		RK73FB2A104J	CHIP R	100K	J	1/10W	1	D14,15		*			ABSORBER			
	R222	1		RK73F82A223J	CHIP 8	22K	J	1/10W	1	016		*	MA77	DIODE			ĸ	
	R223,224	1		RK73FB2A102J	CHIP R	1.0K	J	1/10W	1	017	Į		1SV269.		AP DIODE			2M3
I		1			}				1	019-21			1	DIODE	5.000		"	-
l	R225			RK73FB2A472J	CHIP R	4.7K	j	1/10W		D112			MA112	DIODE			1	
	R226,227		1	RK73F82A103J	CHIP 8	10K	J	1/10W	1	D201		1	MA110	ZENER	DIODE			
- 1	R228	1		RK73FB2A223J	CHIP R	22K	J	1/10W		0202			DTZ7.5(B)	1	DIQUE			
	R229	1	1	RK73FB2A473J	CHIP R	47K	J	1/10W	1	D203,204			MA729	DIODE			1	
j	R230,231		1	RK73FB2A103J	CHIP R	10K	j	1/10W		D205,206		1	MA110	DIODE				
	.,200,201	1								0207			MA729	3000	ic.			
ı	R234		-	R92-0670-05	. CHIP R	0 OHM	1		М	IC1		-	KCD10	IC (FM !	r)			
- 1	R234 R235			RK73FB2A103J	CHIP R	10K	j	1/10W	K.	11		1			A 1 4) F (OL II		v	
i			1	RK73FB2A222J	CHIP R	2.2K	Ĵ	1/10W	K,M2M3	IC2	1		TA7787AF .		AM IF/3V)		K	
	8236 8236	.		RK73F82A821J	CHIP R	820	J	1/10W	М	IC3	İ	1	LA4446	IC (AF F	OWER AMP)			
	18746	1		LIBAGESCANDELL	1 (41)(1)		•		1		1							

PARTS LSIT

TX-RX UNIT (X57-4970-XX)
PLL (X58-4390-00)
PLL (X58-4400-00)

Ref. No. Notes Parts Parts No. Description Nation	PLL (X58-	Address	New	Parts No.	Description	Desti-
ICG		Audress	parts	1	 	
ICO	1.					K
Color		1			1	
IC10	1					
	1			TA7808S	IC (VOLTAGE REGULATOR/ +8V)	
	1				In Leaves on State of	
IC201	ł · · ·	}		1		1
10201				1		
IC207						1
IC208	1			BU4S66	IC (ANALOG SWITCH)	
IC208	1				10 (05 1) 15 10	
IC209	1			1		
IC210				1		
IC211					1 7	
IC301	1 '			l	1 .	
IC301						
C201		ļ ·				.
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DTA114YK	1 '		- 1	1.3.		IC,IVIZIVIO
Q4					DIGITAL TRANSISTOR	K
Q4	00			'DTOLOG IV	DIOCTAL TRANSPOTOR	
Q5					F .	[^K]
DB						
DTC143EK						_K
DTC363EK DIGITAL TRANSISTOR DTC144WK DIGITAL TRANSISTOR DTC144WK DIGITAL TRANSISTOR DTC144WK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC364EK DIGITAL TRANSISTOR DTC364EK DIGITAL TRANSISTOR DTC364EK DTC	1 1				DIGITAL TRANSISTOR	: .
DTC363EK DIGITAL TRANSISTOR DTC144WK DIGITAL TRANSISTOR DTC144WK DIGITAL TRANSISTOR DTC144WK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC363EK DIGITAL TRANSISTOR DTC364EK DIGITAL TRANSISTOR DTC364EK DIGITAL TRANSISTOR DTC364EK DTC		1				
D13,14	1 3		i	• •		^K
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D16-18			- 1		i i	
D20	1 1					
D20		ĺ	-			
O21			İ		!	
Q22		- 1				
DTC124EK DIGITAL TRANSISTOR		Ì	- 1			i
Q26						
Q26	.					
D27		- 1	- 4			- 1
D28						
C29,30	1					
C1		ĺ	- 1		1, -,	- 1
Q32	,		ı			1
DTC123JK			- 1	1		1
Q201			- 1		· · · · · · · · · · · · · · · · · · ·	,
DTC114EK DIGITAL TRANSISTOR			•	I		<i>r</i>
DECIDENCE CRASEBIH102K CHIP C 1000PF K CR			- 1	I		
DTC:14EK DIGITAL TRANSISTOR TRANSISTOR		-				- 1
D205 2SC4116(Y) TRANSISTOR			- 1			
PLL (X58-4390-00): M,M2,M3 C1	- 1		- 1	- 1		
C1	UZU3			1004110[1]	TIMANJOTON	
C2 CK73FB1H102K CHIP C 1000PF K C3 CC73FCH1H020C CHIP C 2.0PF C C4.5 CK73FB1H472K CHIP C 4700PF K C6 CC73FCH1H010C CHIP C 1.0PF C C7-9 CK73FB1H102K CHIP C 1000PF K C10 CK73FB1H472K CHIP C 4700PF K C11 CK73FB1H102K CHIP C 1000PF K			PL	L (X58-4390	-00) : M,M2,M3	
C3	C1		10		· ·	
C4,5 CK73FB1H472K CHIP C			- 1	′ 1		
C6 CC73FCH1H010C CHIP C 1.0PF C C7-9 CK73FB1H102K CHIP C 1000PF K C10 CK73FB1H472K CHIP C 4700PF K C11 CK73FB1H102K CHIP C 1000PF K			- 1			
C7-9 CK73FB1H102K CHIP C 1000PF K C10 CK73FB1H472K CHIP C 4700PF K CK73FB1H102K CHIP C 1000PF K CK73FB1H102K CHIP C 1000PF K CHIP C 1000		ĺ	ž		1	
C10 CK73FB1H472K		-	ď		J J 1.011 U	
C11 CK73FB1H102K CHIP C 1000PF K	C7-9		ļ	K73FB1H102K	CHIP C 1000PF K	- 1
		1			1	
UST CCC/3FCHTH1000 CHIP C 10PF 0		_		I		
	(3)		1	-C/3FCH IN 1000	onir o juri v	

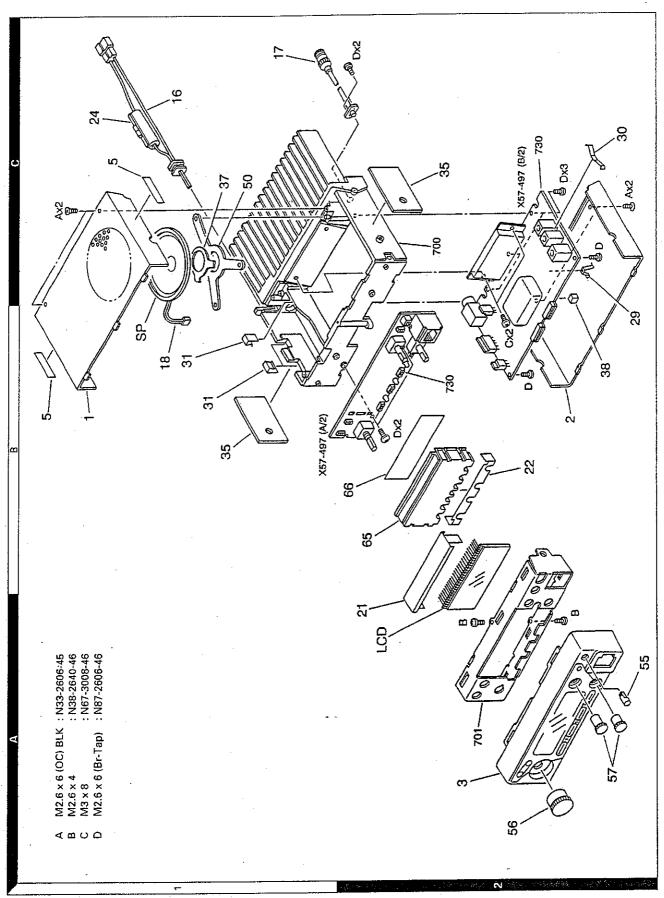
Ref. N	lo.	Address	New			Description	on	Desti- nation
C52				CK73FB1H102K	CHIPC	1000PF	K	
C53				CC73FCH1H100D	CHIPC	10PF	Đ	
C54	,			CK73FB1H102K	CHIPC	1000PF	K	
C55				CK73FB1H223K	CHIP C	0.022UF	K	
C56				CK73FB1E393K	CHIP C	0.039UF	K	
1000			ĺ					
C101				CK73FB1H223K	CHIPC	0.022UF	K.	
C102,10	13			C92-0009-05	CHIP-TAN	4.7UF	10WV	
C104				CK73FB1H102K	CHIPC	1000PF	ĸ	
C105				C92-0003-05	CHIP-TAN	0.47UF	25WV	
C106	į			CK73FB1H223K	CHIP C	0.022UF	K :	
1	ı							
C109,11	0		-	CK73FB1H102K	CHIP C	1000PF	K	
CN1	- {			E40-0311-05	PIN ASSY			
CNZ	i	ļ		E40-0411-05	PIN ASSY			
CN3		i		E40-5201-05	PIN ASSY			
10110					1			
L1				L40-1581-80	SMALL FIX	ED INDUCTOR	150nH	
L2	· Í	ļ		L40-3391-19	II.	ED INDUCTOR		
L3,4	- 1	-		L40-4791-19	SMALL FIX	ED INDUCTOR	4.7UH	
L5			*	134-4456-05	1	ī		
L51				L40-3392-81		ED INDUCTOR	3.3UH	
	1			175 5552 51				
R1	- }			RK73FB2A472J	CHIP R	4.7K J	1/10W	
R2	- 1	1		RK73F82A561J	CHIP R	560 J	1/10W	
R3	- 1	İ		RK73FB2A101J	CHIP R	100 J	1/10W	
R4	- 1	Ì		RK73FB2A121J	CHIP R	120 J	1/10W	
R5	- }			RK73FB2A470J	CHIP R	47 J	1/10W	
	- 1	•		1,1,1,2,1,1,1,1,1,1,1,1,1,1,1,1,1,1,1,1			,,,,,,,,	
R6,7		1		R92-0670-05	CHIP R	0 OHM		
R8				RK73FB2A101J	CHIP R	100 J	1/10W	
R9				RK73FB2A470J	CHIP R	47 J	1/10W	
R10		ļ		RK73FB2A103J	CHIP R	10K J	1/10W	
R51		İ		RK73FB2A103J	CHIP R	10K J	1/10W	
1	ļ						.,	
R52				RK73FB2A223J	CHIP R	22K J	1/10W	
R53	i	}	1	RK73FB2A221J	CHIP R	220 J	1/10W	
R54		- 1	- 1	RK73FB2A472J	CHIP R	4.7K J	1/10W	j
R55		Ī		RK73FB2A473J	CHIP R	47K J	1/10W	
B101				RK73FB2A152J	CHIP R	1.5K J	1/10W	
0400				Opp oggo or	GIUD D	0.01114		
8102		- 1		R92-0670-05	CHIP R	0 OHM		
R103	-	i	ĺ	RK73FB2A222J	CHIP R	2.2K J	1/10W	
R104	- 1		ı	R92-0670-05	CHIP R	0 OHM		
R105				RK73FB2A222J	CHIP R	2.2K J	1/10W	
R106				RK73FB2A392J	CHIPR	3.9K J	1/10W	
2107 111	.			RK73FB2A473J	CHIP R	47K J	1/10W	
R107-111	'	1	-	RK73FB2A473J	CHIP R		· .	
R112	Į		Į	RK73FB2A223J	CHIP R	22K J	1/10W]
R113	I		ı	R92-0670-05	CHIP R	4.7K J 0.0HM	1/10W	Ì
R114			*	HVU363A	DIODE	u Oravi	}	
D1,2			*	NVUSDSA	DIUDE			
IC51		ĺ	1	M54959FP	IC (PLL FREC	DENCY SYNT	HESIZFRI	
Ω1	1		. [2SC2059K(P)	TRANSISTO			
02				2SK508NV(K52)	FET			
Q51			- 1	2SC2059K(P)	TRANSISTO	R		1
Q52		ļ	- 1	DTC144EK	DIGITAL TRA		-	
USZ	1		- 1	DIGIAMEN	יווטוואג וווי	111011611		
Q53			- 1	2SC2412K{Q}	TRANSISTO	R	į	
Q101,102		ļ	- 1	2SC3324(B)	TRANSISTO			
2101,102				20002701				
			 ,	PLL (X58-4	1400-00) : K		
C1			1	CK73FB1E223K	CHIP C	0.022UF	ĸ	
C2,3		ĺ		CK73FB1H102K	CHIP C		к	
C4	1	İ		CK73FB1E223K	CHIP C		κ	
C5	}		- 1	CK73FB1H471K	CHIP C		к	
C6.7				C92-0507-05	CHIP-TAN		6.3WV	
	_L							

PARTS LIST

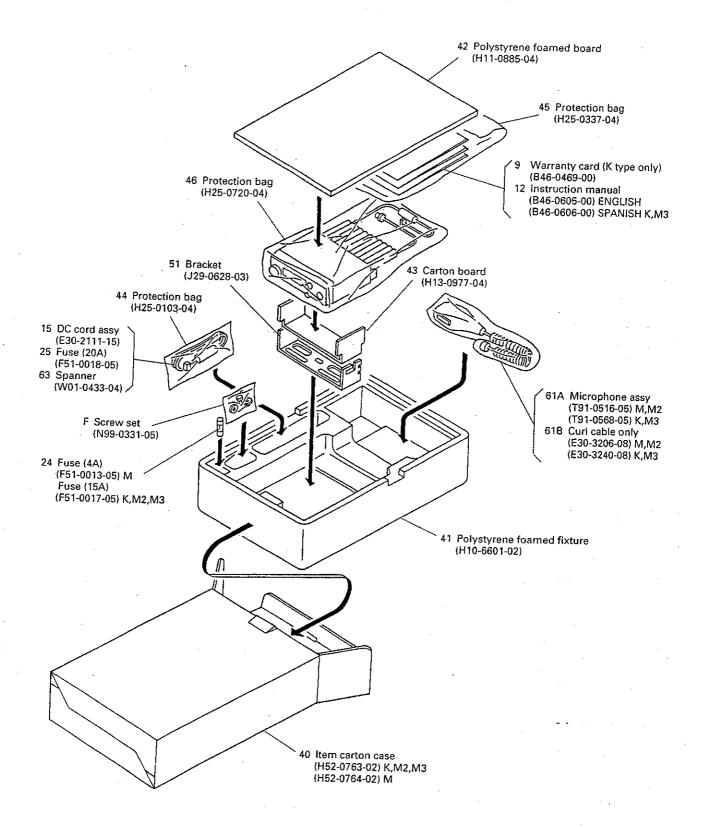
PLL (X58-4400-00)

Ref. No.	Address	New	Parts No.	Description		Desti- nation	Ref. No.	Address	New parts	Parts No.	Description	Des nati
08 09 010		hairs	C92-0003-05 CK73EB1E473K CC73FCH1H050C	CHIP-TAN 0.47UF 25 CHIP C 0.047UF K CHIP C 5.0PF C	1		01 02 02			2SC3324(B) 2SC3324(B) 2SC3324(G)	TRANSISTOR TRANSISTOR TRANSISTOR	
.10 :11,12 :13,14			CK73FB1H102K CK73FB1E223K	CHIP C 1000PF K	:		Q3 Q4			2SC2412K(Q) 2SC2059K(P)	TRANSISTOR TRANSISTOR	
101			CK73G81E103K	CHIP C 0.010UF K			Q101 Q102			2SK508NV(K52) DTC114EK	FET DIGITAL TRANSISTOR	
102		İ	CC73GCH1H030C	CHIP C 3.0PF C		i i	0103			2SC3120	TRANSISTOR	
103,104		ĺ	CK73G81E103K CC73GCH1H010C	CHIP C 1.0PF C		1	Q104			2SK508NV(K52)	FET	
105 106			CC73GCH1H220J	CHIP C 22PF J			Q105			OTC114EK	DIGITAL TRANSISTOR	
107,108			CK73GB1H102K	CHIP C 1000PF K CHIP C 0.010UF K			Q106			2SC3120	TRANSISTOR	
109,110			CK73GB1E103K CC73GCH1H030C	CHIP C 3.0PF C					- 1			i
111 112,113			CK73GB1E103K	CHIPC 0.010UF K		1						
114			CC73GCH1H01GC	CHIP C 1.0PF C								
115 116			CC73GCH1H220J CK73GB1H102K	CHIP C 22PF J CHIP C 1000PF K	1							
N1			E40-5201-05	PIN ASSY								
N101 N102			E40-0411-05 E40-0311-05	PIN ASSY PIN ASSY								
1			L40-3391-19 L40-4791-19	SMALL FIXED INDUCTOR 3							•	
01,102 03		*	L34-4470-05	COIL 2T	1.7011						j	1
04-106		"	L40-4791-19	SMALL FIXED INDUCTOR 4	4.7UH							
07		*	L34-4471-05	COIL 2T								
08			L40-4791-19	SMALL FIXED INDUCTOR	4.7UH							
1-5			RK73GB1J473J		1/16W	.	1					İ
6			RK73GB1J152J		1/16W 1/16W		1					
7 8			RK73GB1J222J RK73GB1J392J	******	1/16W	1						
9			RK73GB1J222J		1/16W							
10,11			RK73G81J103J		1/16W							
13			RK73GB1J472J		1/16W							
14			RK73GB1J473J	• • • • • • • • • • • • • • • • • • • •	1/16W 1/16W					}		
15 16			RK73GB1J223J RK73GB1J103J		1/16W				ļ			
17 <i>-</i>			RK73GB1J2Z₹J		1/16W							
18			R92-1252-05	CHIPR OOHM	1/16W		1			}		
101 102			RK73GB1J101J RK73GB1J470J		1/16W							
103			RK73GB1J470J		1/16W							
104			RK73GB1J222J	*****	1/16W							
105			RK73G81J472J		1/16W							1
106			RK73GB1J471J		1/16W 1/16W					1		
107 108			RK73G81J101J RK73G81J470J		1/16W							
		- `	RK73GB1J682J		1/16W							
109 110			8K73G81J470J	•	1/16W			1		1		
111			RK73GB1J151J		1/16W							
112			RK73GB1J222J	CHIP R 2.2K J	1/16W					1		İ
113			RK73GB1J472J	CHIPR 4.7K J	1/16W	.	-			1		
114			RK73GB1J471J	CHIP R 470 J	1/16W					De	unloaded by	
101,102			1SV269	VARI-CAP DIODE							wnloaded by	
103		*	HVU363A	DIODE VARI-CAP DIODE				1	1	Radi	oAmateur.EU	
104 1			1SV269 M54959FP	IC (PLL FREQUENCY SYNTH	HESIZERI				1		1	1
11		1	2SC2713(B)	TRANSISTOR	-		1	ļ			·	

EXPLODED VIEW



PACKING



ADJUSTMENT

Measuring Equipment for Adjustment

- Tester
 - Input impedance: High
- 2. RF valve voltmeter (RF V.M) Input impedance: $1M\Omega$ or more, 2pF or less Voltage range: Full scale = 10mV to 300V Measurable frequency range: Up to 450MHz
- Frequency counter (f. counter)
 Input sensitivity: About 50mV
 Measurable frequency: 450MHz or more
- DC power supply Voltage: Variable in the range 10 to 17V
- Current: 13A or more 5. Power meter

Measurement power: 60W, 3W, 1W

Impedance: 50Ω

Measurable frequency: 450MHz

AF valve voltmeter (AF V.M)
 Input range: Full scale = 1mV to 30V

Measurable frequency range: 50Hz to 10kHz

- 7. AF generator (AG)
 Output frequency: 100Hz to 10kHz
 Output voltage: 0.5mV to 1V
- Line detector Measurable frequency: 450MHz
- Spectrum analyzer Measurable frequency: 450MHz
- 10. Directional coupler
- 11. Oscilloscope

High sensitivity with horizontal input terminal

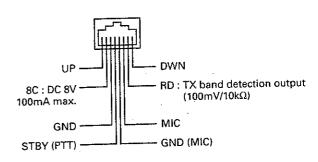
- Standard signal generator (SSG)
 The standard signal generator must be able to generate the 144 and 430MHz band frequencies and vary the amplitude and frequency.
 Output: -20 to 100dBμ
- 13. Dummy load 8Ω about 5W
- 14. Noise generator

The noise generator must be able to generate noise similar to ignition noise containing high-frequency components of 450MHz or more.

- 15. Sweep generator

 The sweep generator must be able to sweep the
 144 and 430MHz bands.
- 16. Tracking generator

Preparation



Microphone socket (as viewed from the front of the set)

- Use an insulated rod, such as a plastic rod, for adjustment (especially for trimmers, coils, etc.).
- To protect the signal generator, never connect the microphone socket when the receiver section is adjusted.
- Before the power cord is connected, make sure the power switch is off.
- See the instruction manual for transmit and receive operations.

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ADJUSTMENT

Common Section

		Mea	sureme	ent		Ad	ustment	g :6:10it
Item	Condition	Test- equipment	Unit	Terminal	Unit	Parts	Method	Specifications/Remarks
1. Setting	1) Source voltage : DC 13.8V POWER : OFF VOL, SQŁ knob : Minimum							
2. Reset	1) MR key + POWER ON After the check, MR key : Press						Check	All indicator of LCD on.
3. PLL	1) Frequency : 146.000MHz Transmit/Receive	DC V.M Dummy load	TX-RX Rear panel	TP2 ANT			Check	RX : 1.2 to 9.0V TX : 1.2 to 9.0V
4. Transmission frequency	1) Frequency : 146.000MHz Transmit	f. counter Power meter	Rear panel	ANT	TX-RX	TC1	146.000MHz	±100Hz

Receiver Section

		Mea	sureme	ent		Adj	ustment	
item	Condition	Test- equipment	Unit	Terminal	Unit	Parts	Method	Specifications/Remarks
1. BPF	1) Frequency: 146.05MHz K,M2,M3 145.04MHz M SSG output: -93dBm MOD: 1.0kHz DEV: ±3.0kHz	Tester SSG Oscilloscope	TX-RX Rear panel	TP1 ANT EXT. SP	TX-RX	Ł1~L6	For max, voltage of TP1, align from L1 to L6.	
	2) SSG output : -113dBm						For max. voltage of TP1, repeat the alignment from L1 to L6, twist.	
2. Sensitivity	1) Frequency K,M2,M3: 146.05, 144.05, 147.95MHz M: 145.04, 144.04, 145.94MHz SSG output: -121dBm K -122dBm M,M2,M3 AF: 0.63V/8Ω	Distortion meter AF V.M Oscilloscope	Rear panel	EXT. SP			Check	More than SINAD 12dB
3. Distortion	1) Frequency : 146.05MHz K,M2,M3 145.04MHz M SSG output : –53dBm AF : 4.0V/βΩ						Check	Less than 3.0%
4. Hum and Noise ratio	1) Frequency : 146.05MHz K,M2,M3 145.04MHz M SSG output : -53dBm MOD : OFF AF : 2.83V/8Ω	SSG AF V.M Oscilloscope	Rear panel	ANT EXT. SP		,	Check	More than S/N 46dB
5, S-meter	1) Frequency : 146.05MHz K,M2,M3 145.04MHz M SSG output : -95dBm	SSG	Rear panel	ANT	TX-RX	VR1	Align so that all the S-meter go on, then the last segment goes off. Check	All S-meter segments on.
	2) SSG output : -93dBm 3) SSG output : OFF						CHECK -	S-meter segments off.

ADJUSTMENT

		Measurement			Adjustment				
item	Condition	Test- equipment	Unit	Terminal	Unit	Parts	Method	Specifications/Remarks	
6. Squelch	1) Frequency: 146.05MHz, K,M2,M3 145.04MHz M SSG output: OFF Align so that noise is not audible by SQL knob.	SSG Ammeter Oscilloscope	Rear panel	ANT EXT. SP			Check	Maker position of SQL knob 8:00-11:00 BUSY indication off. Less than 0.6A	
	2) SSG output : -127dBm						Check	Squelch opens. BUSY indication on.	
	3) SSG output : -113dBm SQL knob : Maximum After the check, SQL knob : Minimum		·				Check	Squelch opens.	

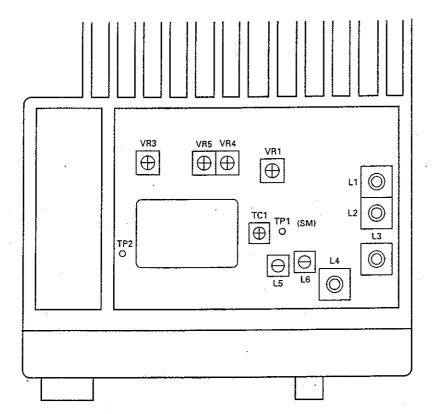
Transmitter Section

•		Me	ent		Ad	justment]	
Item	Condition	Test- equipment Unit Te		Terminal	Unit	Parts	Method	Specifications/Remarks
1. Power	1) Frequency : 146.000MHz K,M2,M3 144:98MHz M TX-RX unit VR4 : Maximum Transmit	Power meter Ammeter	Rear panel	ANT			Check	More than 55.0W K,M2,M3 More than 13.0W M ON AIR indication on. All RF-meter segments on.
·	2) Frequency : 146.000MHz K,M2,M3 144.98MHz M Transmit			;	TX-RX	VR4	52.0W K,M2,M3 12.0W M	±1.0W, Less than 11.0A K,M2,M3 ±1.0W, Less than 3.5A M
	3) Frequency: K,M2,M3 : 144.00, 147.975MHz M : 144.00, 145.98MHz Transmit						Check	44.0~60.0W, Less than 11.0A K,M2,M3 10.0~14.0W, Less than 3.5A M
	4) F key → LOW key (M on.) Frequency: 146,000MHz K,M2,M3 144,98MHz M Transmit			i proprio de la companya de la compa	TX-RX	VR5	12.0W K,M2,M3 1.0W M	±1.0W K,M2,M3 ±0.15W M
	5) F key → LOW key (i. on.) Frequency : 146,000MHz K,M2,M3 144,98MHz M Transmit						Check	3.0~8.0W K,M2,M3 0.3~0.8W M
2. DEV	1) Frequency: 146.000MHz	Modulation analyzer Oscilloscope	Rear panel	ANT	TX-RX	VR3	±4.4kHz (Align absolute value of + or ~ value.)	±0.2kHz No abnormal oscilloscope wave.
	1 -,	AG AF V.M	Front panel	MIC			Check	±2.2~3.6kHz Nor abnormal oscilloscope wave.
3. Tone	K,M2,M3		Rear panel	ANT			Check -	±0.5~1.5kHz

ADJUSTMENT

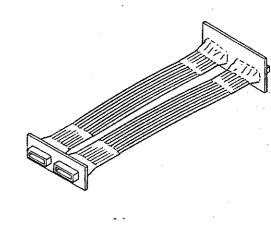
		Measurement				Aď	ljustment	
item	Condition	Test- equipment	Unit	Terminal	Unit	Parts	Method	Specifications/Remarks
4. Single tone	1) POWER: OFF MHz key + REV key + POWER ON Frequency: 146.000MHz K,M2,M3 144.98MHz M Transmit	Modulation analyzer Oscilloscope	panel	ANT			Check	±0.8~1.5kHz
5. DTMF	1) Frequency : 146.000MHz K,M2,M3 144.98MHz M Press the DTMF key of transmission jig.						Check	More than ±2.2kHz
6. Protection	1) Frequency: 146.000MHz K,M2,M3 144.98MHz M POWER: HI (F key + LOW key) ANT: Open and short Transmit	Ammeter					Check	Less than 11.0A K,M2,M3 Less than 4.0A M
7. CTCSS	1) Only TSU-8 is installed set. Frequency : 145.100MHz (CTCSS : 88.5Hz) TX-RX-communicate between		Rear panel	ANT			Check	Their sets are able to TX-RX-communicate.
I	testing set and monitor set. 2) Frequency: 145.100MHz (CTCSS: 103.5Hz)		· . !		, 			Their sets are not able to TX-RX-communicate.

Adjustment Points



Jig (13 Pin Flat cable)

This is the same cable as TM-241's cable.



TC1: Transmission frequency

L1~6: BPF VR1: S-meter VR3: DEV VR4: HI power VR5: MID power

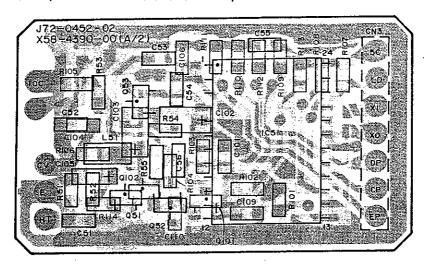
TERMINAL FUNCTION

TX-RX Unit (X57-4970-XX)

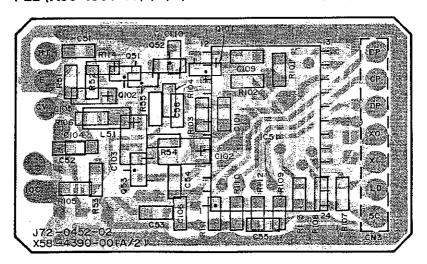
CN No.	Pin No.	Name	Function
CN1	1	Ε	GND
ĺ	2	SP	Speaker input.
CN3	1	É	GND.
	2	JK2	Destination data output.
ľ	3	DT2	Shift register (IC5) enable.
	4	JK1	Destination data output.
	5	EP1	PLL enable.
ŀ	6	CK	PLL clock.
	7	DT1	PLL data.
	8	DET	CTCSS detector output.
	9	RD	Audio output.
	10	SC	Squeich busy control output.
	11	SQ	Squelch output.
	12	SM	S-meter output.
	13	E	GND.
CN4	1	E	GND.
	2	В	+13.8V.
		PSW	Power switch control input.
	4	NC	
	5	8C	Common +8V.
	6	BEEP	Beep input (To audio IC from CPU).
	7	A2	Audio input
			(To AF power amplifier from AF volume).
	8	A1	Audio output (To AF volume).
	9	AE	GND.
	10	TONE	Tone input.
	11	ME	MIC GND.
	12	МО	Modulation input.
	13	<u>E</u>	GND.
CN201	1	E	GND.
ĺ	2	JK2	Destination data input.

1	CN No.	Pin No.	Name	Function
1		3	DT2	Shift register data output (From CPU IC201).
İ		4	JK1	Destination data input.
1		5	EP1	PLL enable (From CPU IC201).
I		6	CK	PLL clock (From CPU IC201).
		- 7	DT1	PLL data (From CPU IC201).
1		8	DET	CTCSS detector output.
L		9	RD	Audio input.
L		10	SC	Squelch busy control input (To CPU IC201).
l		11	SQ	Squelch input (To CPU IC201).
1		12	SM	S-meter input (To CPU (C201).
l		13	É	GND.
i	CN202	1	Е	GND.
ı		2 .	В	+13.8V.
ı		3	PSW	Power switch control output (From CPU IC201).
l	<u> </u>	4	NÇ	
1	ļ	5.	8C	Common +8V.
l		6	BEEP	Beep output(From CPU IC201).
		7	A2	Audio output (From AF volume).
•		8	A1	Audio input (To AF volume).
ļ		9	AE	GND
Ì		10	TONE	TONE output (From CPU IC201).
L		11	ME	MIC GND.
ı	1	12	MO	Modulation output(From MIC amplifier).
١		13	E	GND.
١	CN203	1	RD	CTCSS unit voice de-modulation input.
ı		2	5C	+5V.
ı		3	E	GND.
ļ		4	SDO	CTCSS unit tone matching input.
		5	TO	Not used.
1		6	STC	CTCSS unit connect/enable output.
l		7	DTC	CTCSS unit data output.
ı	1	8	CKC	CTCSS unit clock output.

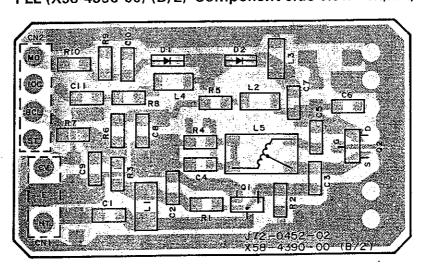
Downloaded by RadioAmateur.EU PLL (X58-4390-00) (A/2) Component side view M,M2,M3



PLL (X58-4390-00) (A/2) Foil side view M,M2,M3



PLL (X58-4390-00) (B/2) Component side view M,M2,M3

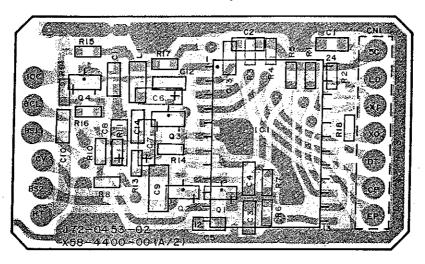


Component side

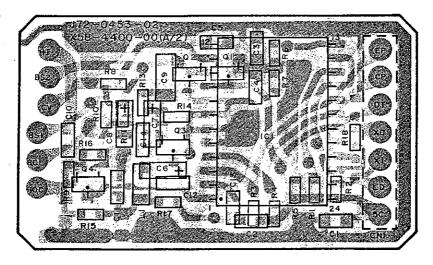
Foil side

PC BOARD VIEWS TM-261A

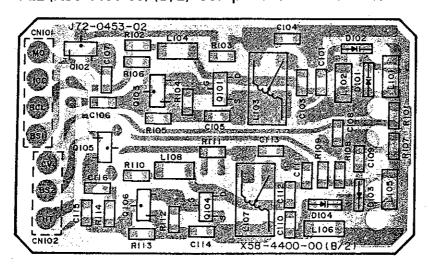
PLL (X58-4400-00) (A/2) Component side view K



PLL (X58-4400-00) (A/2) Foil side view K



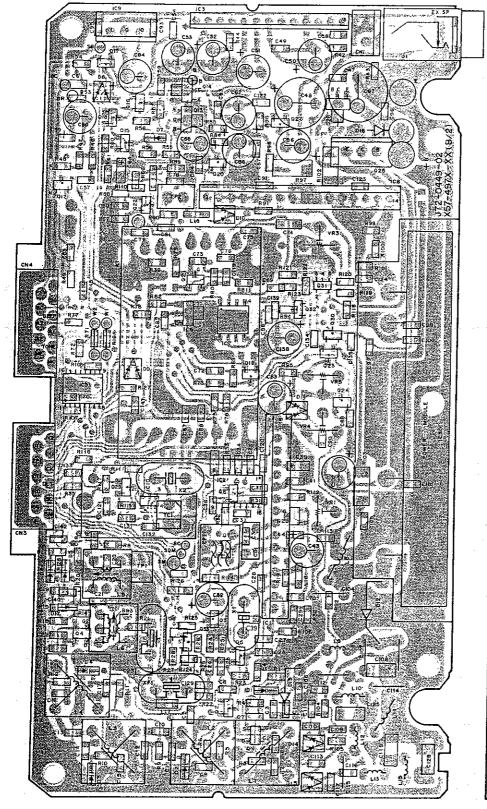
PLL (X58-4400-00) (B/2) Component side view K

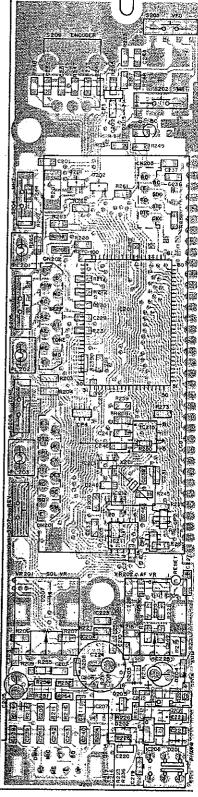


Component side
Foil side

TM-261A PC BOARD VIEWS

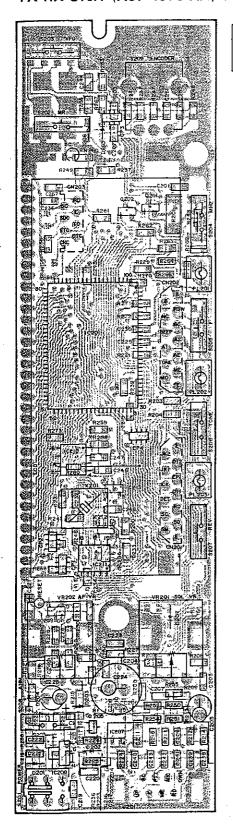
TX-RX UNIT (X57-4970-XX) Component side view -11 : K -21 : M -22 : M2 -23 : M3

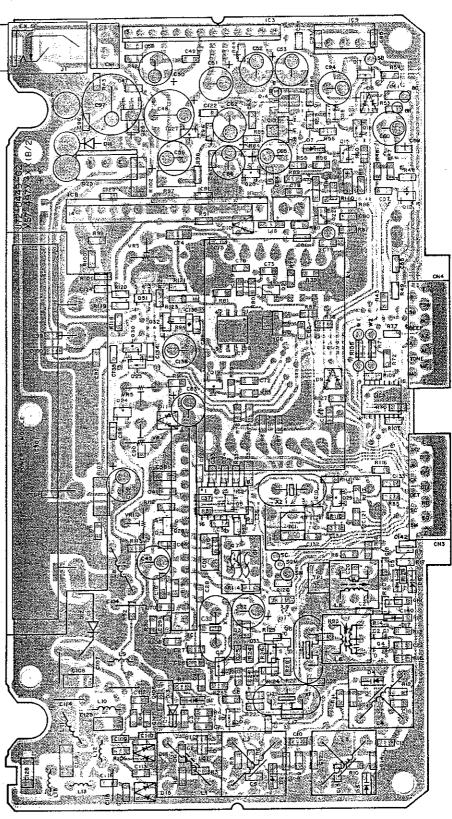




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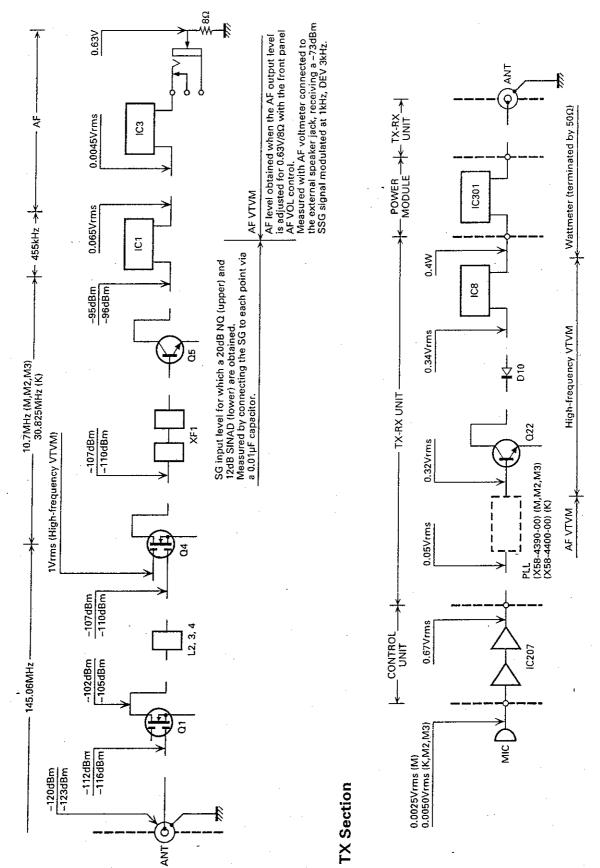
TX-RX UNIT (X57-4970-XX) Foil side view -11 : K -21 : M -22 : M2 -23 : M3





Foil side

LEVEL DIAGRAM



1. AG is set so that MIC input becomes 3kHz DEV at 1kHz MOD. 2. Transmitting frequency : 145.06MHz

RX Section

SPECIFICATIONS

General	
Frequency range	144 to 148MHz
Mode	F3E (FM)
Antenna impedance	50Ω
Usable temperature range	20°C to +60°C (-4°F to +140°F)
Power supply	13.8V DC ± 15% (11.7 to 16.0V)
Grounding method	Negative ground
Current	· · · · · · · · · · · · · · · · · · ·
Transmit (max.)	11.0A or less (K,M2,M3) 3.5A or less (M)
Receive (no signal)	
Frequency stability	Within ±10ppm
Dimensions (W x H x D projections not included)	140 x 40 x 160.5 mm / 5-1/2" x 1-9/16" x 6-5/16"
Weight	1.0kg / 2.2lb
Transmitter	
Power output	
High	50W (K.M2.M3) 10W (M)
Medium	
Low	
Modulation	
Spurious emissions	
Maximum frequency deviation	
Audio distortion (at 60% modulation)	
Microphone impedance	
Receiver	
Circuitry	Double conversion superheteradyna
Intermediate frequency (1st / 2nd)	
U.S.A./Canada	30 825MHz / 455kHz
General	
Sensitivity	
12dB SINAD	0.16uV or less
6dB	
-60dB	
Squelch sensitivity	
Audio output (8Ω, 5% distortion)	2W or higher
Audio output impedance	8Ω
•	

Specifications are subject to change without notice due to developments in technology.

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KENWOOD CORPORATION 14-6, Dogenzaka 1-chome, Shibuya-ku, Tokyo 150, Japan

KENWOOD SERVICE CORPORATION
P.O. 80X 22745, 2201 East Dominguez Street, Long Beach, CA 90801-5745, U.S.A.
KENWOOD ELECTRONICS LATIN AMERICA S.A.
P.O. 80X 55-2791 Piso 6 Plaza Chase Cl. 47 y Aquilino de la Guardio Panama, Republic of Panama

KENWOOD ELECTRONICS CANADA INC. 6070 Kestrel Road, Mississauga, Ontario, Canada L5T 1S8

KENWOOD ELECTRONICS DEUTSCHLAND GMBH

Rembrücker Str. 15, 63150 Heusenstamm, Germany
KENWOOD ELECTRONICS BENELUX N.V.
Mechelsesteenweg 418 B-1930 Zaventem, Belgium

KENWOOD ELECTRONICS FRANCE S.A. 13, Boulevard Ney, 75018 Paris, France

KENWOOD ELECTRONICS U.K. LIMITED KENWOOD House, Dwight Road, Watford, Herts., WD1 8EB United Kingdom

KENWOOD ELECTRONICS NEDERLAND B.V. Amsterdamseweg 35, 1422 AC Uithoorn, The Netherlands

KENWOOD ELECTRONICS ITALIA S.p.A.

Via G. Sirtori, 7/9 20129 Milano, Italy

KENWOOD IBERICA S.A. Bolivia, 239-08020 Barcelona, Spain

KENWOOD ELECTRONICS AUSTRALIA PTY. LTD.

(A.C.N. 001 499 074)

P.O. Box 504, 8 Figtree Drive, Australia Centre, Homebush, N.S.W. 2140, Australia

KENWOOD & LEE ELECTRONICS, LTD. Unit 3712-3724, Level 37, Tower one Metroplaza, 223 Hing Fong Road, Kwai Fong, N.T., Hong Kong